



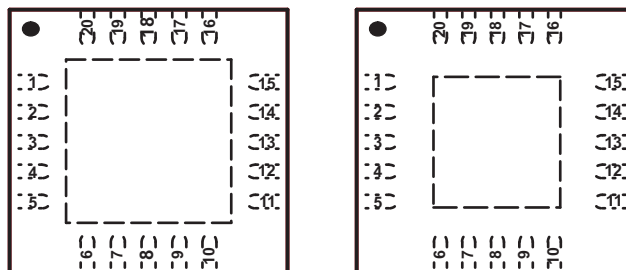
## 80-mW DIRECTPATH™ STEREO HEADPHONE DRIVER

### FEATURES

- **Space Saving Packages**
  - 20-Pin, 4 mm × 4 mm Thin QFN
  - TPA4411 – Thermally Optimized PowerPAD™ Package
  - TPA4411M – Thermally Enhanced PowerPAD™ Package
  - 16-Ball, 2.18 mm × 2.18 mm WCSP
- **Ground-Referenced Outputs Eliminate DC-Bias Voltages on Headphone Ground Pin**
  - No Output DC-Blocking Capacitors
    - Reduced Board Area
    - Reduced Component Cost
    - Improved THD+N Performance
    - No Degradation of Low-Frequency Response Due to Output Capacitors
- **Wide Power Supply Range: 1.8 V to 4.5 V**
- **80-mW/Ch Output Power into 16-Ω at 4.5 V**
- **Independent Right and Left Channel Shutdown Control**
- **Short-Circuit and Thermal Protection**
- **Pop Reduction Circuitry**

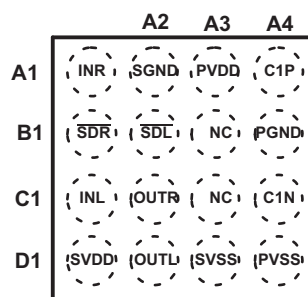
### APPLICATIONS

- Notebook Computers
- CD / MP3 Players
- Smart Phones
- Cellular Phones
- PDAs



TPA4411RTJ

TPA4411MRTJ



TPA4411YZH

### DESCRIPTION

The TPA4411 and TPA4411M are stereo headphone drivers designed to allow the removal of the output DC-blocking capacitors for reduced component count and cost. The TPA4411 and TPA4411M are ideal for small portable electronics where size and cost are critical design parameters.

The TPA4411 and TPA4411M are capable of driving 80 mW into a 16-Ω load at 4.5 V. Both TPA4411 and TPA4411M have a fixed gain of –1.5 V/V and headphone outputs that have ±8-kV IEC ESD protection. The TPA4411 and TPA4411M have independent shutdown control for the right and left audio channels.

The TPA4411 is available in a 2.18 mm × 2.18 mm WCSP and 4 mm × 4 mm Thin QFN packages. The TPA4411M is available in a 4 mm × 4 mm Thin QFN package. The TPA4411RTJ package is a thermally optimized PowerPAD™ package allowing the maximum amount of thermal dissipation and the TPA4411MRTJ is a thermally enhanced PowerPAD package designed to match competitive package footprints.



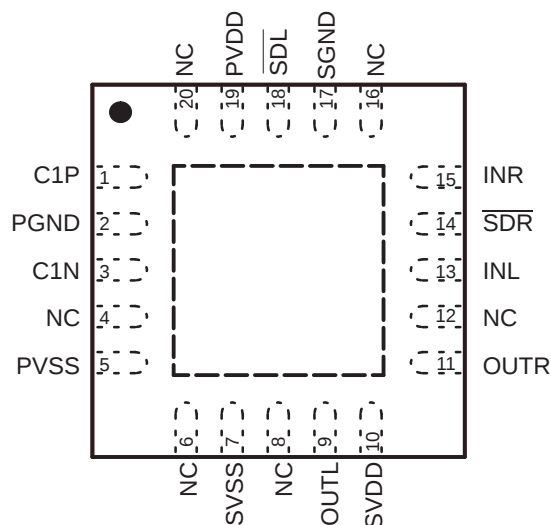
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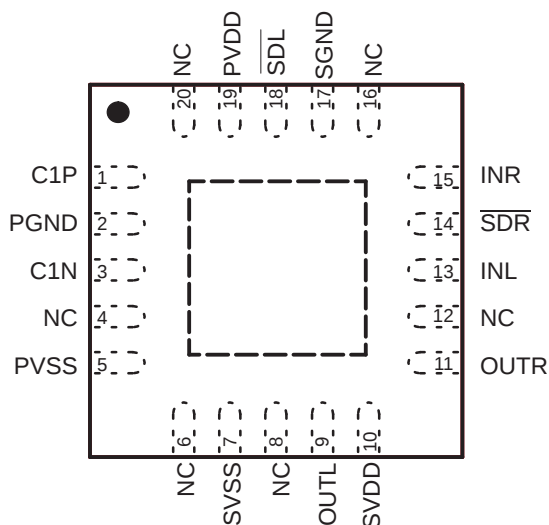
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

**RTJ (QFN) PACKAGE  
(TOP VIEW)**



**TPA4411RTJ**

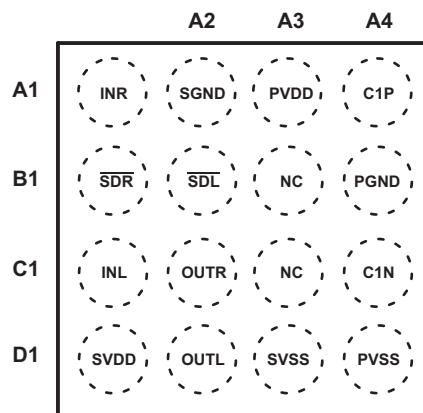
NC – No internal connection



**TPA4411MRTJ**

NC – No internal connection

**YZH (WCSP) PACKAGE  
(TOP VIEW)**



**TPA4411YZH**

NC - No internal connection

## TERMINAL FUNCTIONS

| TERMINAL                |                           |        | I/O | DESCRIPTION                                                                          |
|-------------------------|---------------------------|--------|-----|--------------------------------------------------------------------------------------|
| NAME                    | QFN                       | WCSP   |     |                                                                                      |
| C1P                     | 1                         | A4     | I/O | Charge pump flying capacitor positive terminal                                       |
| PGND                    | 2                         | B4     | I   | Power ground, connect to ground.                                                     |
| C1N                     | 3                         | C4     | I/O | Charge pump flying capacitor negative terminal                                       |
| NC                      | 4, 6, 8,<br>12, 16,<br>20 | B3, C3 |     | No connection                                                                        |
| PVSS                    | 5                         | D4     | O   | Output from charge pump.                                                             |
| SVSS                    | 7                         | D3     | I   | Amplifier negative supply, connect to PVSS via star connection.                      |
| OUTL                    | 9                         | D2     | O   | Left audio channel output signal                                                     |
| SVDD                    | 10                        | D1     | I   | Amplifier positive supply, connect to PVDD via star connection.                      |
| OUTR                    | 11                        | C2     | O   | Right audio channel output signal                                                    |
| INL                     | 13                        | C1     | I   | Left audio channel input signal                                                      |
| $\overline{\text{SDR}}$ | 14                        | B1     | I   | Right channel shutdown, active low logic.                                            |
| INR                     | 15                        | A1     | I   | Right audio channel input signal                                                     |
| SGND                    | 17                        | A2     | I   | Signal ground, connect to ground.                                                    |
| $\overline{\text{SDL}}$ | 18                        | B2     | I   | Left channel shutdown, active low logic.                                             |
| PVDD                    | 19                        | A3     | I   | Supply voltage, connect to positive supply.                                          |
| Exposed Pad             |                           | -      |     | Exposed pad must be soldered to a floating plane. Do NOT connect to power or ground. |

## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

over operating free-air temperature range,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

|                                                              |                                      | VALUE / UNIT                 |
|--------------------------------------------------------------|--------------------------------------|------------------------------|
| Supply voltage, AVDD, PVDD                                   |                                      | –0.3 V to 5.5 V              |
| $V_I$                                                        | Input voltage                        | –0.3 V to $V_{DD} + 0.3$ V   |
| Output Continuous total power dissipation                    |                                      | See Dissipation Rating Table |
| $T_A$                                                        | Operating free-air temperature range | –40°C to 85°C                |
| $T_J$                                                        | Operating junction temperature range | –40°C to 150°C               |
| $T_{stg}$                                                    | Storage temperature range            | –65°C to 150°C               |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds |                                      | 260°C                        |

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## DISSIPATION RATINGS TABLE

| PACKAGE           | $T_A \leq 25^\circ\text{C}$<br>POWER RATING | DERATING FACTOR <sup>(1)</sup> | $T_A = 70^\circ\text{C}$<br>POWER RATING | $T_A = 85^\circ\text{C}$<br>POWER RATING |
|-------------------|---------------------------------------------|--------------------------------|------------------------------------------|------------------------------------------|
| RTJ<br>(TPA4411)  | 5200 mW                                     | 41.6 mW/°C                     | 3120 mW                                  | 2700 mW                                  |
| RTJ<br>(TPA4411M) | 3450 mW                                     | 34.5 mW/°C                     | 1898 mW                                  | 1380 mW                                  |
| YZH               | 1200 mW                                     | 9.21 mW/°C                     | 690 mW                                   | 600 mW                                   |

(1) Derating factor measured with High K board.

## AVAILABLE OPTIONS

| $T_A$         | PACKAGED DEVICES <sup>(1)</sup> | PART NUMBER                | SYMBOL |
|---------------|---------------------------------|----------------------------|--------|
| –40°C to 85°C | 20-pin, 4 mm × 4 mm QFN         | TPA4411RTJ <sup>(2)</sup>  | AKQ    |
|               | 20-pin, 4 mm × 4 mm QFN         | TPA4411MRTJ <sup>(2)</sup> | BPB    |
|               | 16-ball, 2.18 mm × 2.18 mm WSCP | TPA4411YZH                 | AKT    |

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at [www.ti.com](http://www.ti.com).  
 (2) The RTJ package is only available taped and reeled. To order, add the suffix “R” to the end of the part number for a reel of 3000, or add the suffix “T” to the end of the part number for a reel of 250 (e.g., TPA4411RTJR).

## RECOMMENDED OPERATING CONDITIONS

|                                                                       | MIN | MAX                | UNIT |
|-----------------------------------------------------------------------|-----|--------------------|------|
| Supply voltage, AVDD, PVDD                                            | 1.8 | 4.5 <sup>(1)</sup> | V    |
| $V_{IH}$ High-level input voltage $\overline{SDL}$ , $\overline{SDR}$ | 1.5 |                    | V    |
| $V_{IL}$ Low-level input voltage $\overline{SDL}$ , $\overline{SDR}$  |     | 0.5                | V    |
| $T_A$ Operating free-air temperature                                  | –40 | 85                 | °C   |

(1) Device can shut down for VDD > 4.5 V to prevent damage to the device.

## ELECTRICAL CHARACTERISTICS

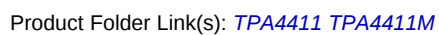
$T_A = 25^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                                                                   | TEST CONDITIONS                                                               | MIN | TYP | MAX  | UNIT |
|-----------------------------------------------------------------------------|-------------------------------------------------------------------------------|-----|-----|------|------|
| VOS  Output offset voltage                                                  | $V_{DD} = 1.8\text{ V to }4.5\text{ V}$ , Inputs grounded                     |     |     | 8    | mV   |
| PSRR Power Supply Rejection Ratio                                           | $V_{DD} = 1.8\text{ V to }4.5\text{ V}$                                       | –69 | –80 |      | dB   |
| $V_{OH}$ High-level output voltage                                          | $V_{DD} = 3\text{ V}$ , $R_L = 16\ \Omega$                                    | 2.2 |     |      | V    |
| $V_{OL}$ Low-level output voltage                                           | $V_{DD} = 3\text{ V}$ , $R_L = 16\ \Omega$                                    |     |     | –1.1 | V    |
| $ I_{IH} $ High-level input current ( $\overline{SDL}$ , $\overline{SDR}$ ) | $V_{DD} = 4.5\text{ V}$ , $V_I = V_{DD}$                                      |     |     | 1    | μA   |
| $ I_{IL} $ Low-level input current ( $\overline{SDL}$ , $\overline{SDR}$ )  | $V_{DD} = 4.5\text{ V}$ , $V_I = 0\text{ V}$                                  |     |     | 1    | μA   |
| $I_{DD}$ Supply Current                                                     | $V_{DD} = 1.8\text{ V}$ , No load, $\overline{SDL} = \overline{SDR} = V_{DD}$ |     | 5.3 | 6.5  | mA   |
|                                                                             | $V_{DD} = 3\text{ V}$ , No load, $\overline{SDL} = \overline{SDR} = V_{DD}$   |     | 6.5 | 8.0  |      |
|                                                                             | $V_{DD} = 4.5\text{ V}$ , No load, $\overline{SDL} = \overline{SDR} = V_{DD}$ |     | 8.0 | 10.0 |      |
|                                                                             | Shutdown mode, $V_{DD} = 1.8\text{ V to }4.5\text{ V}$                        |     |     | 1    | μA   |

## OPERATING CHARACTERISTICS

 $V_{DD} = 3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $R_L = 16\ \Omega$  (unless otherwise noted)

| PARAMETER    |                                      | TEST CONDITIONS                                                           | MIN   | TYP     | MAX   | UNIT                |
|--------------|--------------------------------------|---------------------------------------------------------------------------|-------|---------|-------|---------------------|
| $P_O$        | Output power (Outputs In Phase)      | THD = 1%, $V_{DD} = 3\text{ V}$ , $f = 1\text{ kHz}$                      |       | 50      |       | mW                  |
|              |                                      | THD = 1%, $V_{DD} = 4.5\text{ V}$ , $f = 1\text{ kHz}$                    |       | 100     |       |                     |
|              |                                      | THD = 1%, $V_{DD} = 3\text{ V}$ , $f = 1\text{ kHz}$ , $R_L = 32\ \Omega$ |       | 50      |       |                     |
| THD+N        | Total harmonic distortion plus noise | $P_O = 25\text{ mW}$ , $f = 1\text{ kHz}$                                 |       | 0.054%  |       |                     |
|              |                                      | $P_O = 25\text{ mW}$ , $f = 20\text{ kHz}$                                |       | 0.010%  |       |                     |
|              | Crosstalk                            | $P_O = 20\text{ mW}$ , $f = 1\text{ kHz}$                                 |       | –83     |       | dB                  |
| $k_{SVR}$    | Supply ripple rejection ratio        | 200-mV <sub>pp</sub> ripple, $f = 217\text{ Hz}$                          |       | –82.5   |       | dB                  |
|              |                                      | 200-mV <sub>pp</sub> ripple, $f = 1\text{ kHz}$                           |       | –70.4   |       |                     |
|              |                                      | 200-mV <sub>pp</sub> ripple, $f = 20\text{ kHz}$                          |       | –45.1   |       |                     |
| $A_v$        | Closed-loop voltage gain             |                                                                           | –1.45 | –1.5    | –1.55 | V/V                 |
| $\Delta A_v$ | Gain matching                        |                                                                           |       | 1%      |       |                     |
|              | Slew rate                            |                                                                           |       | 2.2     |       | V/ $\mu\text{s}$    |
|              | Maximum capacitive load              |                                                                           |       | 400     |       | pF                  |
| $V_n$        | Noise output voltage                 |                                                                           |       | 10      |       | $\mu\text{V}_{RMS}$ |
|              | Electrostatic discharge, IEC         | OUTR, OUTL                                                                |       | $\pm 8$ |       | kV                  |
| $f_{osc}$    | Charge pump switching frequency      |                                                                           | 280   | 320     | 420   | kHz                 |
|              | Start-up time from shutdown          |                                                                           |       | 450     |       | $\mu\text{s}$       |
|              | Input impedance                      |                                                                           | 12    | 15      | 18    | k $\Omega$          |
| SNR          | Signal-to-noise ratio                | $P_O = 40\text{ mW}$ (THD+N = 0.1%)                                       |       | 98      |       | dB                  |
|              | Thermal shutdown                     | Threshold                                                                 | 150   |         | 170   | $^\circ\text{C}$    |
|              |                                      | Hysteresis                                                                |       | 15      |       | $^\circ\text{C}$    |



## TYPICAL CHARACTERISTICS

$C_{(PUMP)} = C_{(PVSS)} = 2.2 \mu\text{F}$ ,  $C_{IN} = 1 \mu\text{F}$  (unless otherwise noted)

### Table of Graphs

|                                   |                    | FIGURE |
|-----------------------------------|--------------------|--------|
| Total harmonic distortion + noise | vs Output power    | 1–24   |
| Total harmonic distortion + noise | vs Frequency       | 25–32  |
| Supply voltage rejection ratio    | vs Frequency       | 33, 34 |
| Power dissipation                 | vs Output power    | 35–42  |
| Crosstalk                         | vs Frequency       | 43–46  |
| Output power                      | vs Supply voltage  | 47–50  |
| Quiescent supply current          | vs Supply voltage  | 51     |
| Output power                      | vs Load resistance | 5–60   |
| Output spectrum                   |                    | 61     |
| Gain and phase                    | vs Frequency       | 62, 63 |

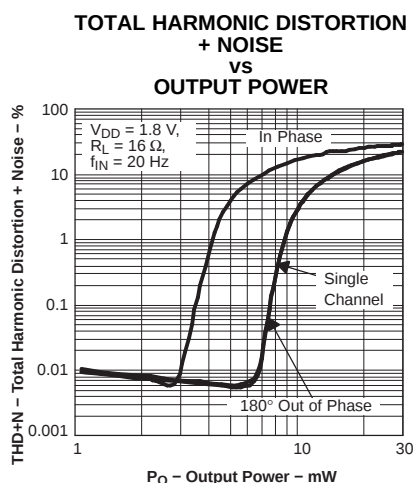


Figure 1.

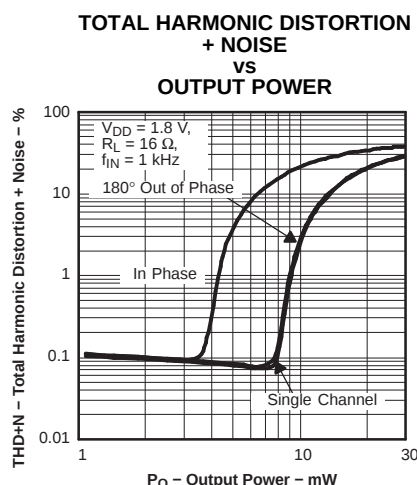


Figure 2.

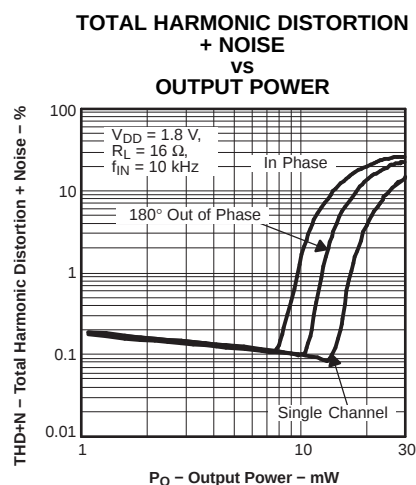


Figure 3.

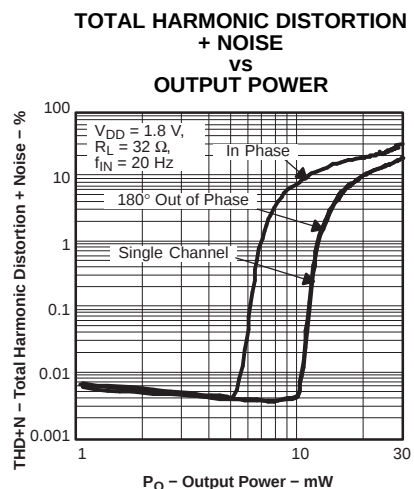


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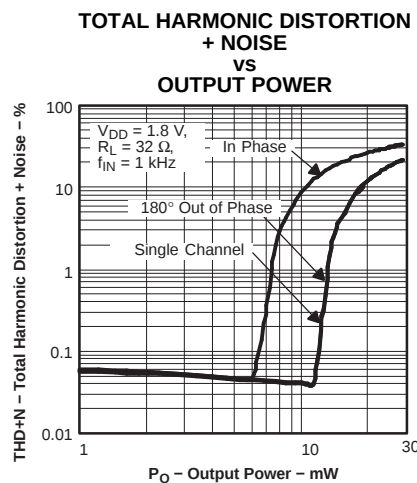


Figure 5.

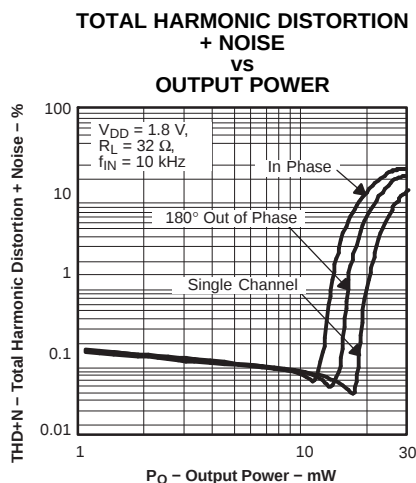


Figure 6.

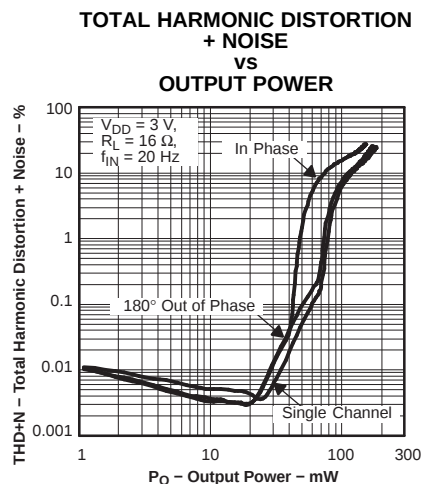


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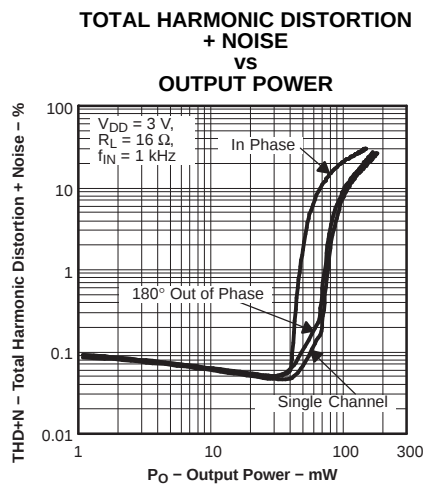


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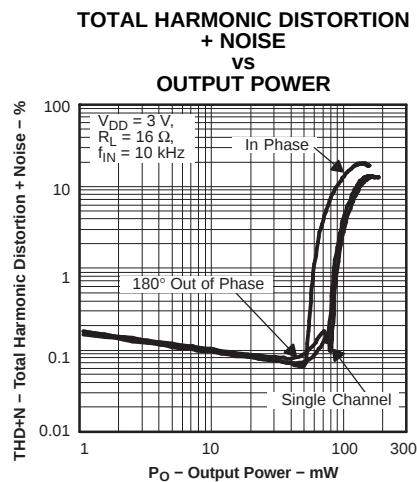


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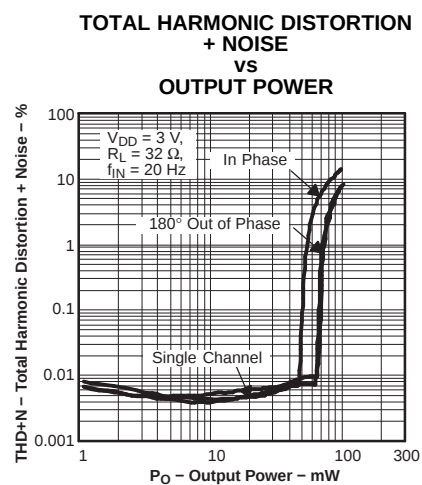


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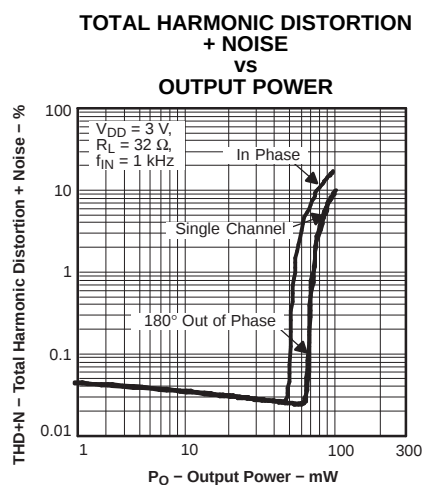


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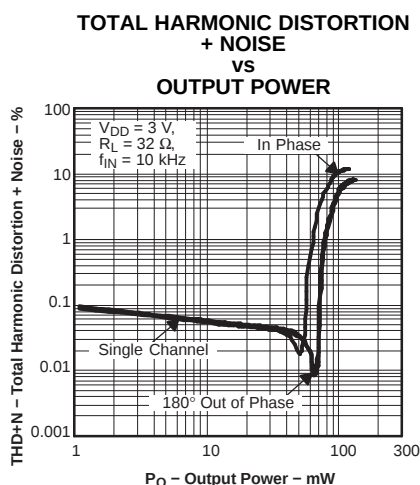


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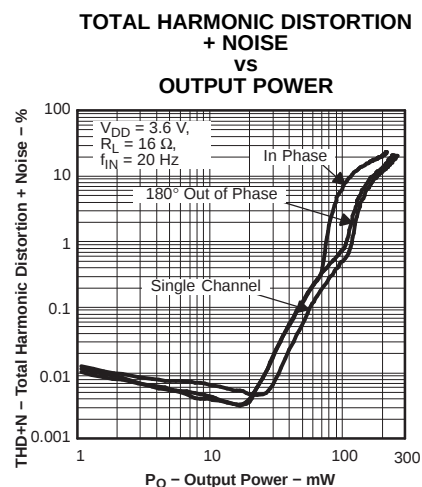


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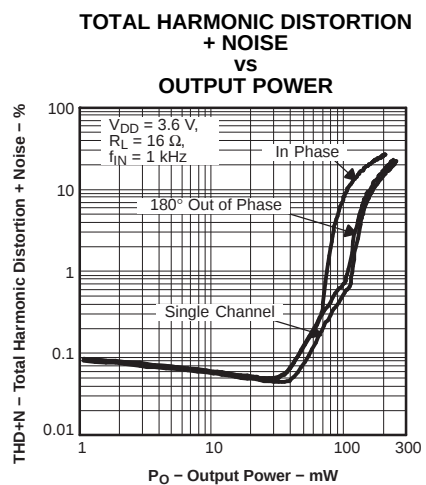


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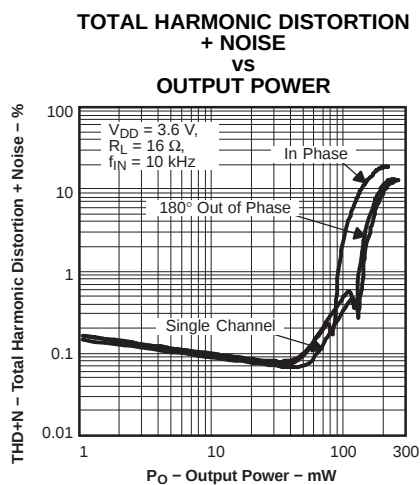


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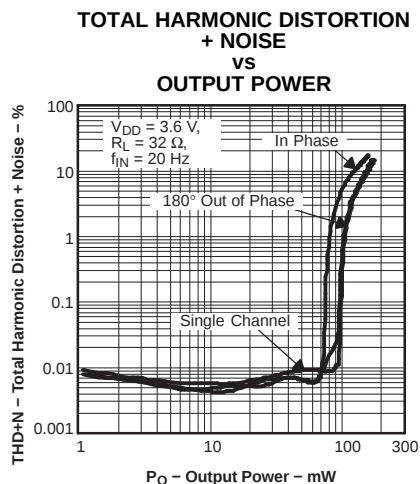


Figure 16.

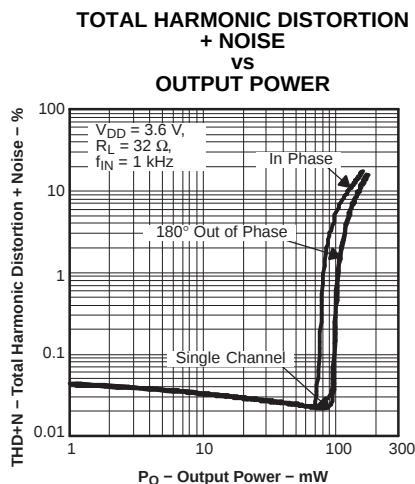


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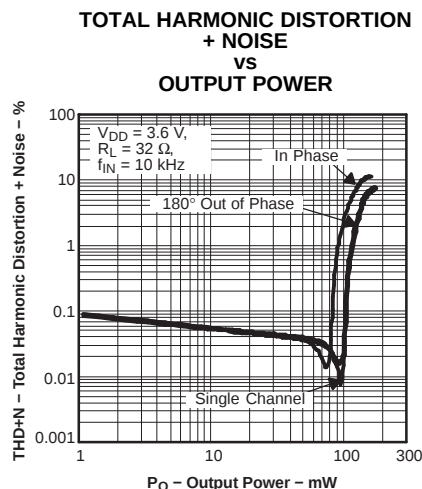


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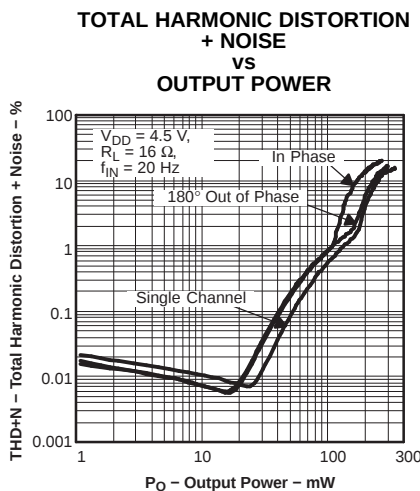


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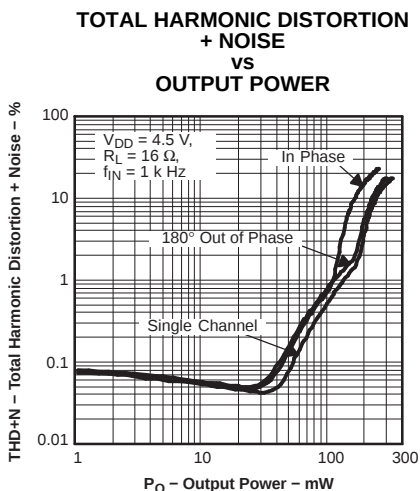


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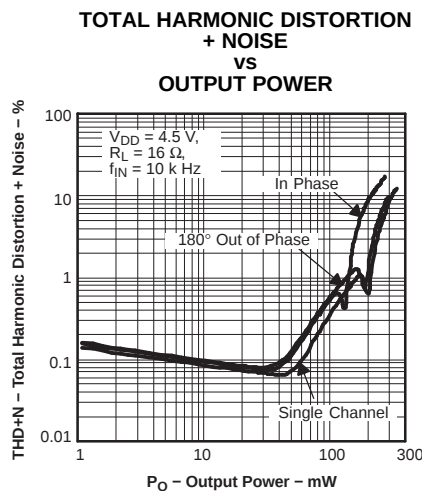


Figure 21.

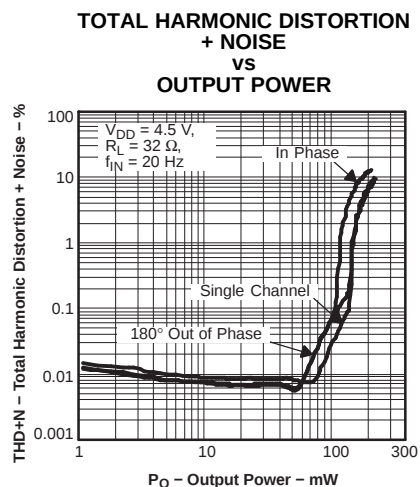


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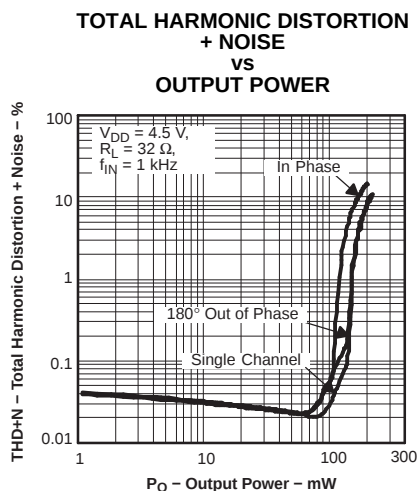


Figure 23.

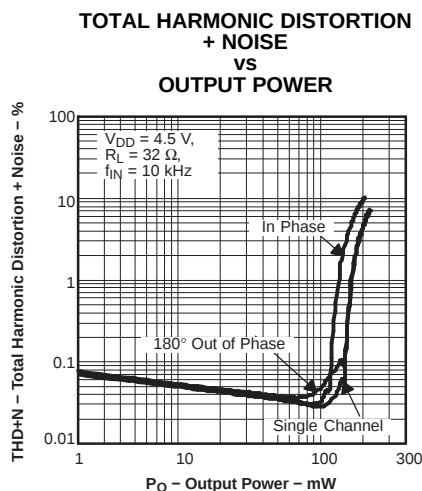


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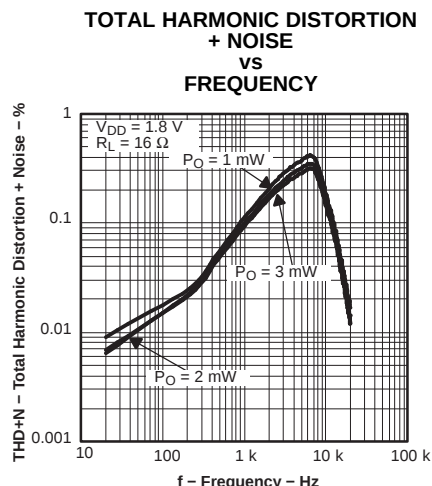


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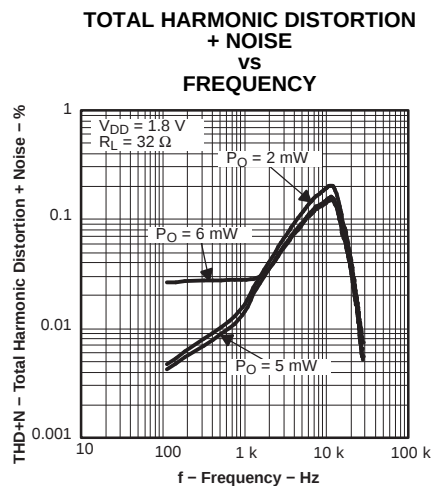


Figure 26.

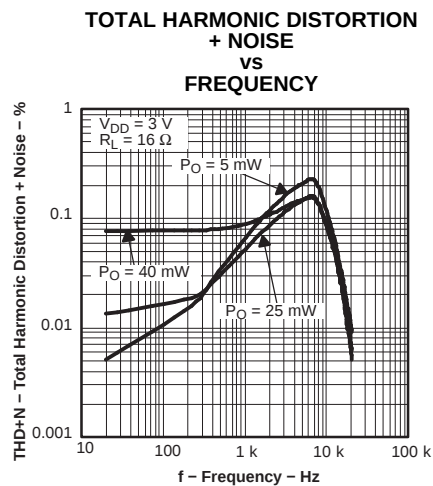


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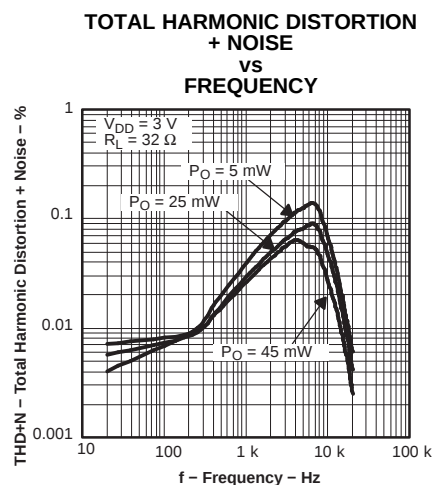


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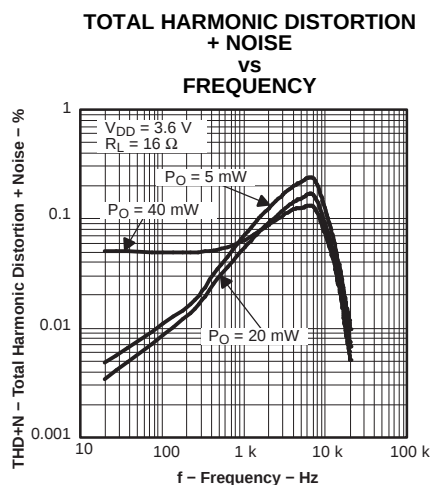


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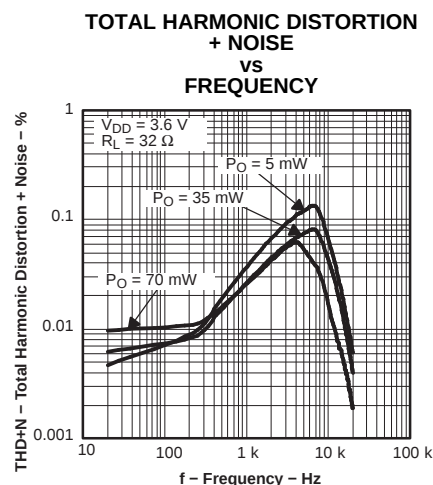


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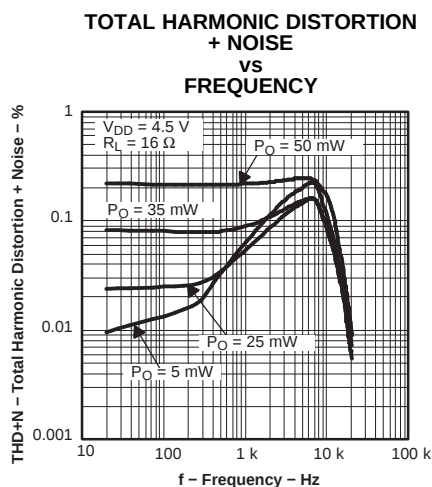


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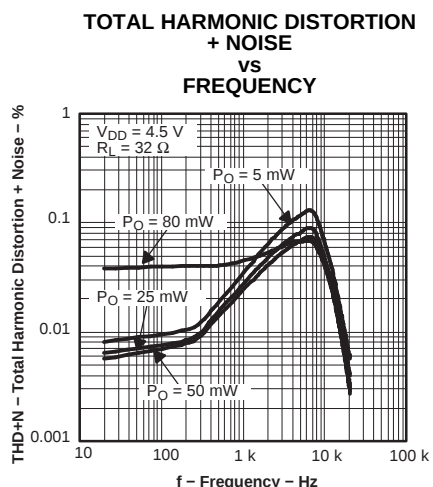


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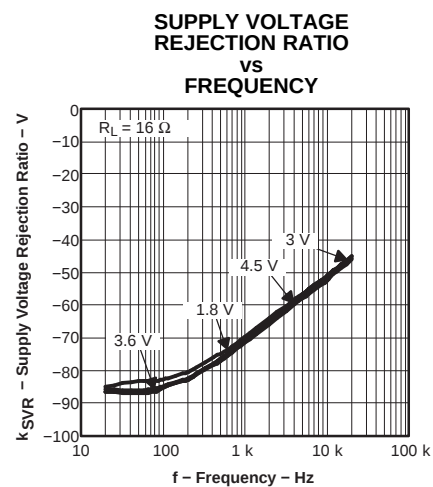


Figure 33.

**SUPPLY VOLTAGE  
REJECTION RATIO  
VS  
FREQUENCY**

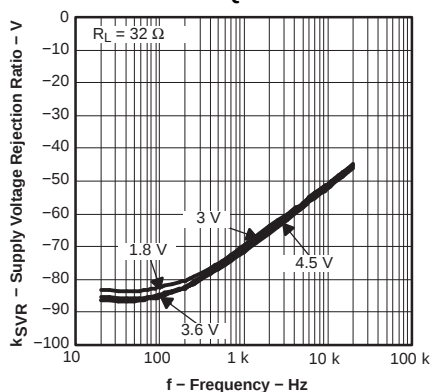


Figure 34.

**POWER DISSIPATION  
VS  
OUTPUT POWER**

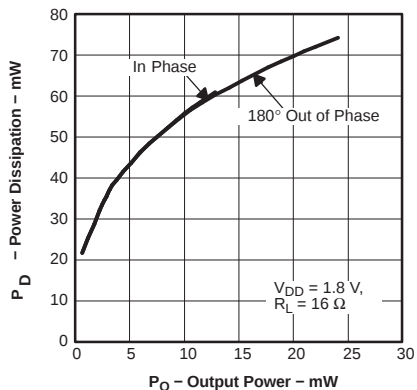


Figure 35.

**POWER DISSIPATION  
VS  
OUTPUT POWER**

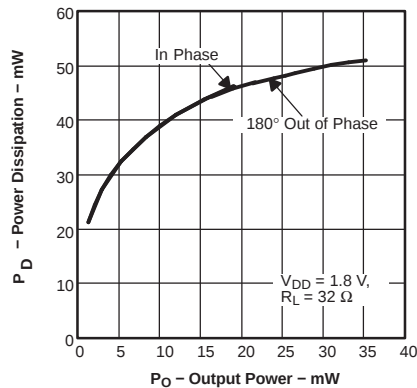


Figure 36.

**POWER DISSIPATION  
VS  
OUTPUT POWER**

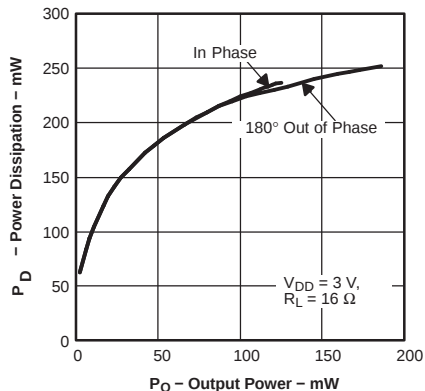


Figure 37.

**POWER DISSIPATION  
VS  
OUTPUT POWER**

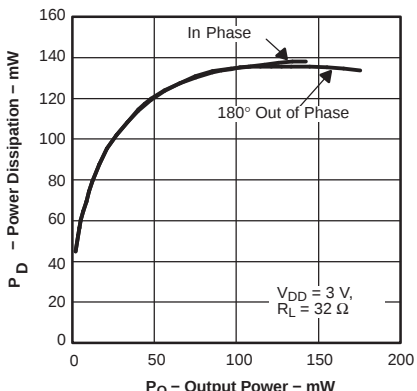


Figure 38.

**POWER DISSIPATION  
VS  
OUTPUT POWER**

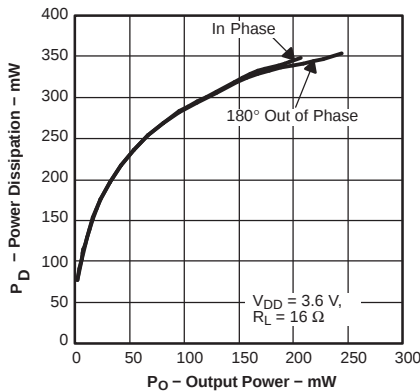


Figure 39.

**POWER DISSIPATION  
VS  
OUTPUT POWER**

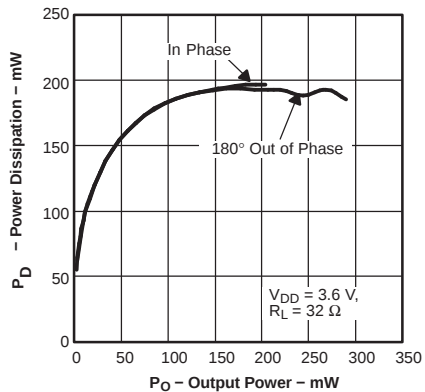


Figure 40.

**POWER DISSIPATION  
VS  
OUTPUT POWER**

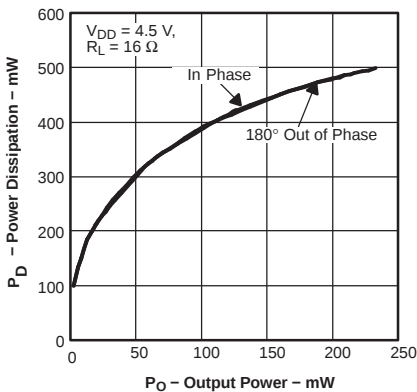


Figure 41.

**POWER DISSIPATION  
VS  
OUTPUT POWER**

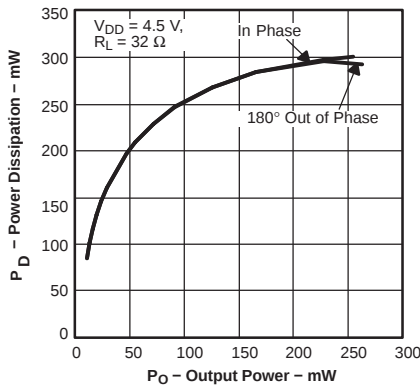
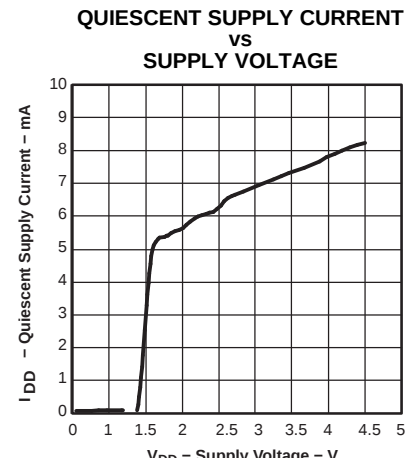
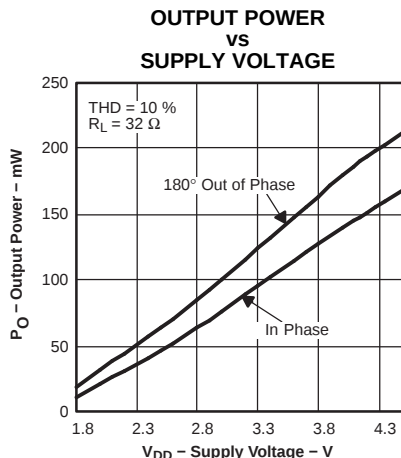
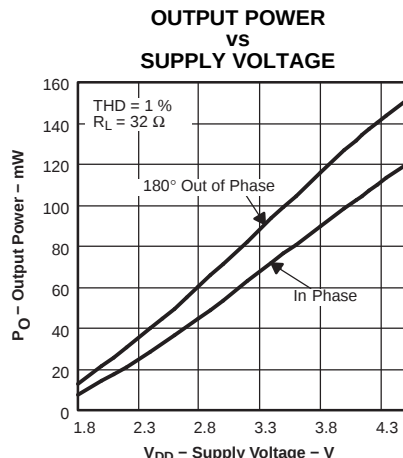
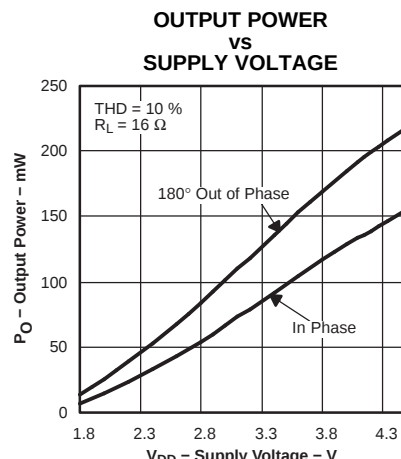
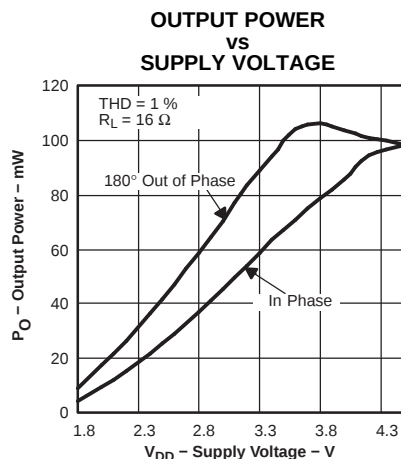
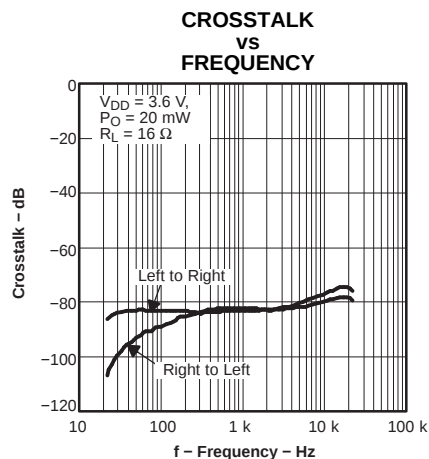
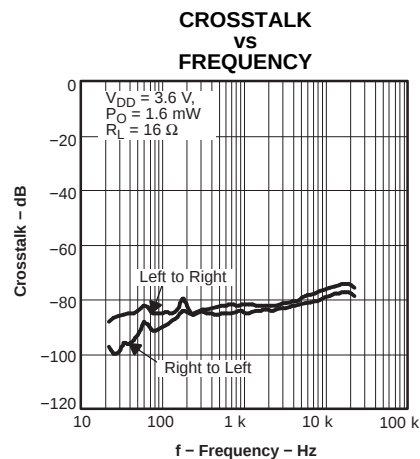
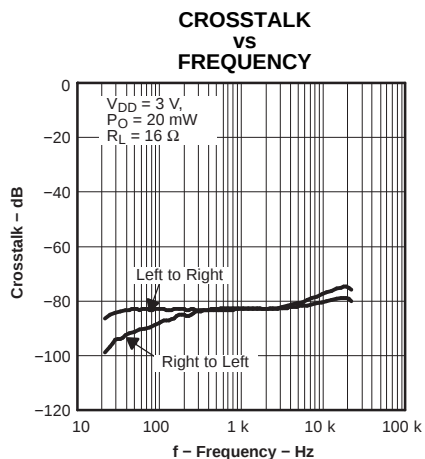
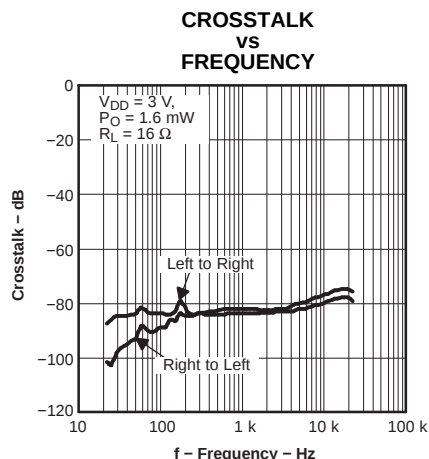


Figure 42.



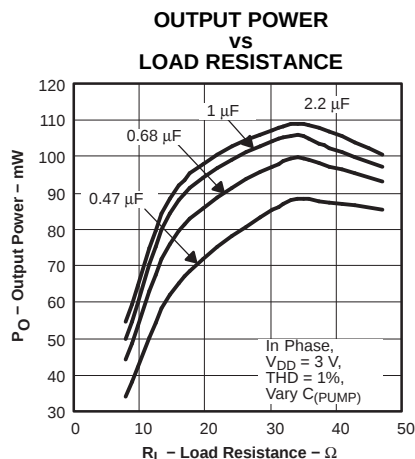


Figure 52.

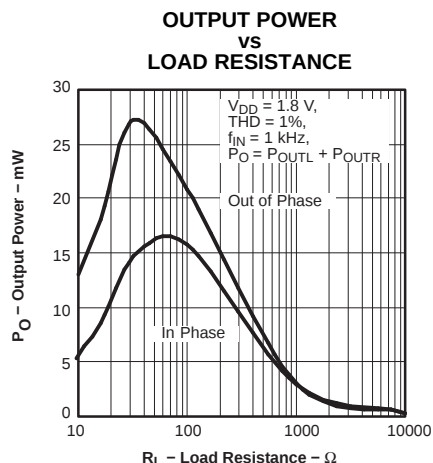


Figure 53.

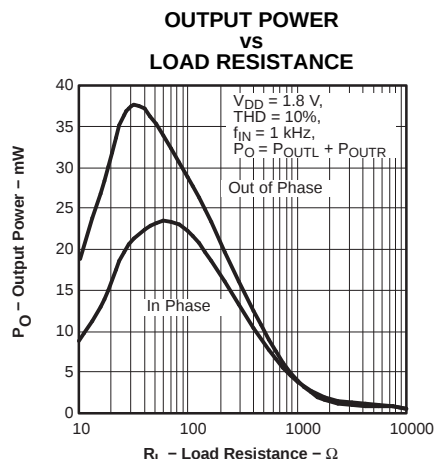


Figure 54.

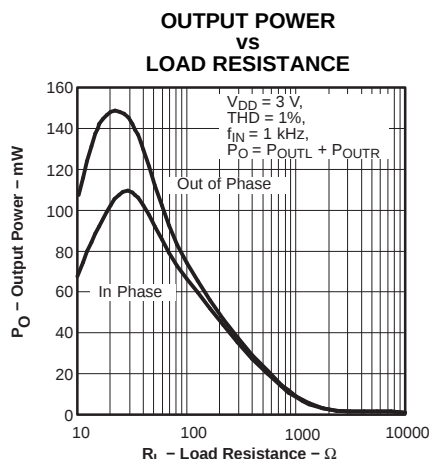


Figure 55.

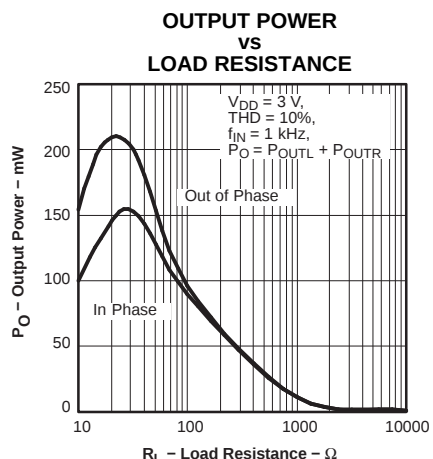


Figure 56.

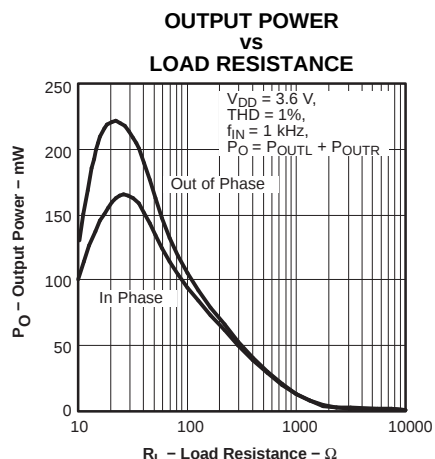


Figure 57.

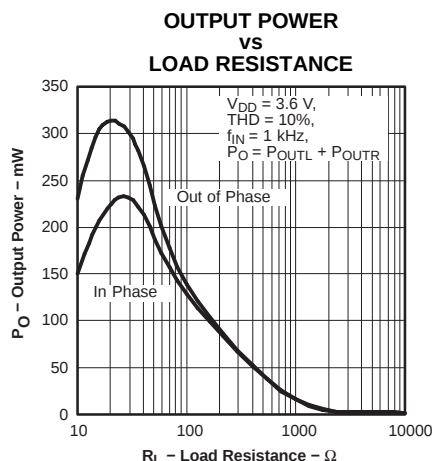


Figure 58.

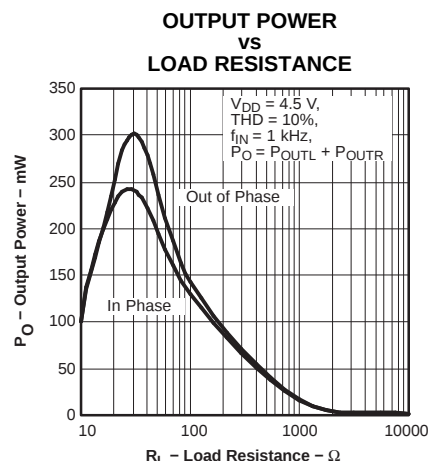


Figure 59.

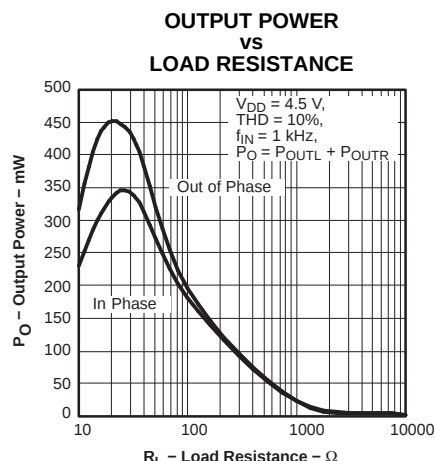


Figure 60.

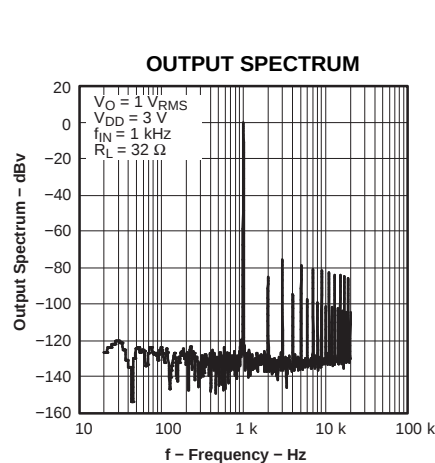


Figure 61.

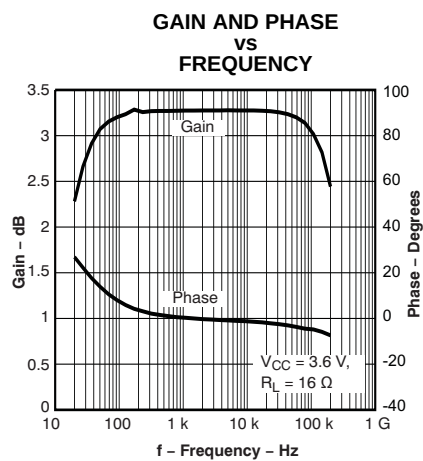


Figure 62.

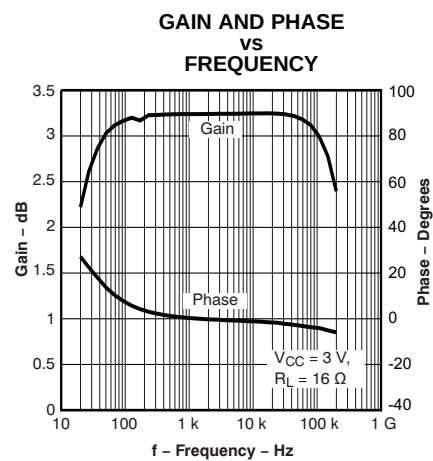


Figure 63.

## APPLICATION INFORMATION

### Headphone Amplifiers

Single-supply headphone amplifiers typically require dc-blocking capacitors. The capacitors are required because most headphone amplifiers have a dc bias on the outputs pin. If the dc bias is not removed, the output signal is severely clipped, and large amounts of dc current rush through the headphones, potentially damaging them. The top drawing in [Figure 64](#) illustrates the conventional headphone amplifier connection to the headphone jack and output signal.

DC blocking capacitors are often large in value. The headphone speakers (typical resistive values of 16 Ω or 32 Ω) combine with the dc blocking capacitors to form a high-pass filter. [Equation 1](#) shows the relationship between the load impedance ( $Z_L$ ), the capacitor ( $C_O$ ), and the cutoff frequency ( $f_c$ ).

$$f_c = \frac{1}{2\pi R_L C_O} \quad (1)$$

$C_O$  can be determined using [Equation 2](#), where the load impedance and the cutoff frequency are known.

$$C_O = \frac{1}{2\pi R_L f_c} \quad (2)$$

If  $f_c$  is low, the capacitor must then have a large value because the load resistance is small. Large capacitance values require large package sizes. Large package sizes consume PCB area, stand high above the PCB, increase cost of assembly, and can reduce the fidelity of the audio output signal.

Two different headphone amplifier applications are available that allow for the removal of the output dc blocking capacitors. The Capless amplifier architecture is implemented in the same manner as the conventional amplifier with the exception of the headphone jack shield pin. This amplifier provides a reference voltage, which is connected to the headphone jack shield pin. This is the voltage on which the audio output signals are centered. This voltage reference is half of the amplifier power supply to allow symmetrical swing of the output voltages. Do not connect the shield to any GND reference or large currents will result. The scenario can happen if, for example, an accessory other than a floating GND headphone is plugged into the headphone connector. See the second block diagram and waveform in [Figure 64](#).

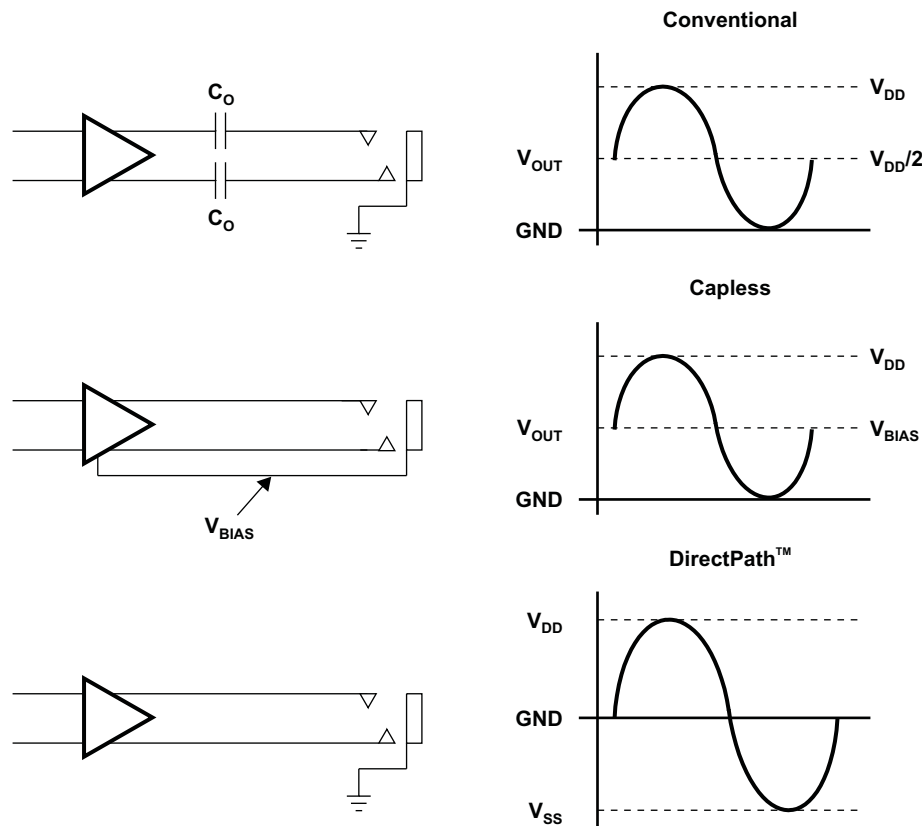


Figure 64. Amplifier Applications

The DirectPath™ amplifier architecture operates from a single supply but makes use of an internal charge pump to provide a negative voltage rail. Combining the user provided positive rail and the negative rail generated by the IC, the device operates in what is effectively a split supply mode. The output voltages are now centered at zero volts with the capability to swing to the positive rail or negative rail. The DirectPath™ amplifier requires no output dc blocking capacitors, and does not place any voltage on the sleeve. The bottom block diagram and waveform of Figure 64 illustrate the ground-referenced headphone architecture. This is the architecture of the TPA4411.

### Input-Blocking Capacitors

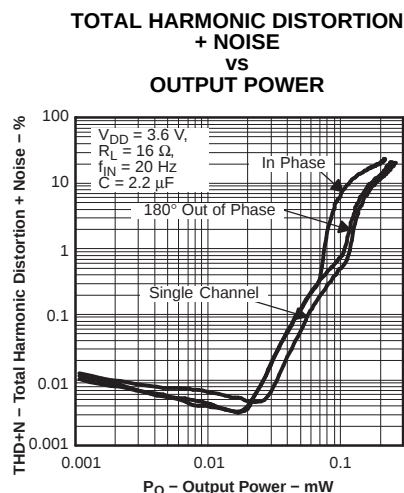
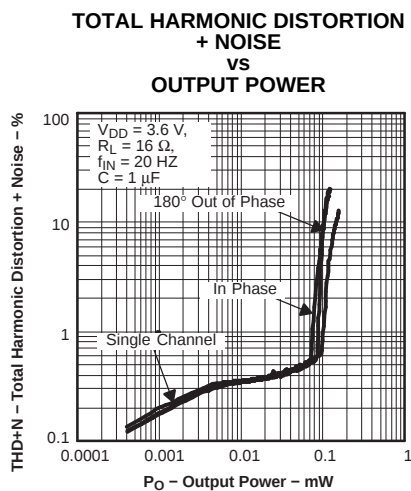
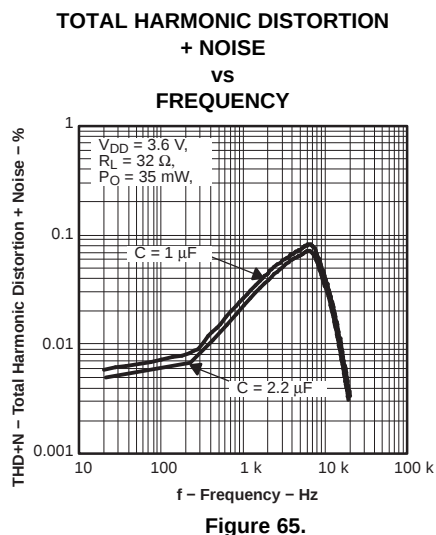
DC input-blocking capacitors are required to be added in series with the audio signal into the input pins of the TPA4411 and TPA4411M. These capacitors block the DC portion of the audio source and allow the TPA4411 and TPA4411M inputs to be properly biased to provide maximum performance.

These capacitors form a high-pass filter with the input impedance of the TPA4411 and TPA4411M. The cutoff frequency is calculated using Equation 3. For this calculation, the capacitance used is the input-blocking capacitor and the resistance is the input impedance of the TPA4411 or TPA4411M. Because the gains of both the TPA4411 and TPA4411M are fixed, the input impedance remains a constant value. Using the input impedance value from the operating characteristics table, the frequency and/or capacitance can be determined when one of the two values are given.

$$f_{C_{IN}} = \frac{1}{2\pi R_{IN} C_{IN}} \quad \text{or} \quad C_{IN} = \frac{1}{2\pi f_{C_{IN}} R_{IN}} \quad (3)$$

## Charge Pump Flying Capacitor and PVSS Capacitor

The charge pump flying capacitor serves to transfer charge during the generation of the negative supply voltage. The PVSS capacitor must be at least equal to the charge pump capacitor in order to allow maximum charge transfer. Low ESR capacitors are an ideal selection, and a value of 2.2  $\mu\text{F}$  is typical. Capacitor values that are smaller than 2.2  $\mu\text{F}$  can be used, but the maximum output power is reduced and the device may not operate to specifications. Figure 65 through Figure 75 compare the performance of the TPA4411 and TPA4411M with the recommended 2.2- $\mu\text{F}$  capacitors and 1- $\mu\text{F}$  capacitors.



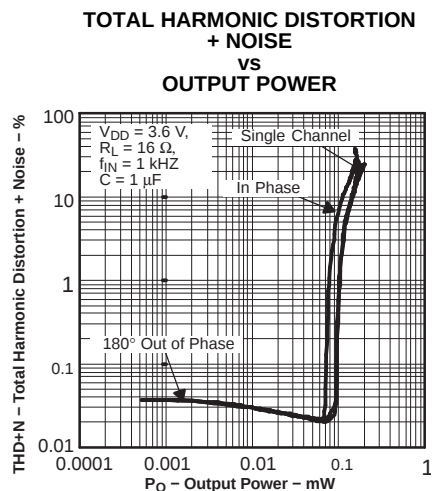


Figure 68.

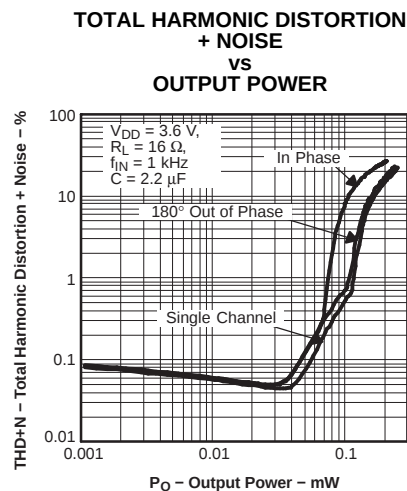


Figure 69.

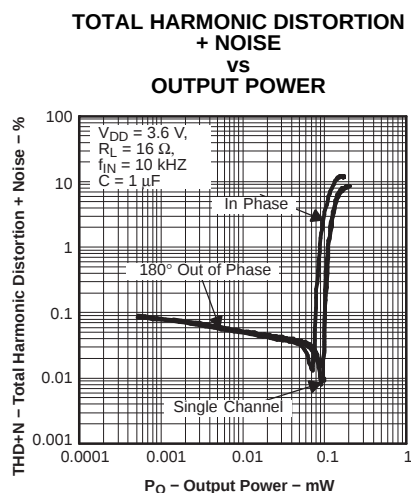


Figure 70.

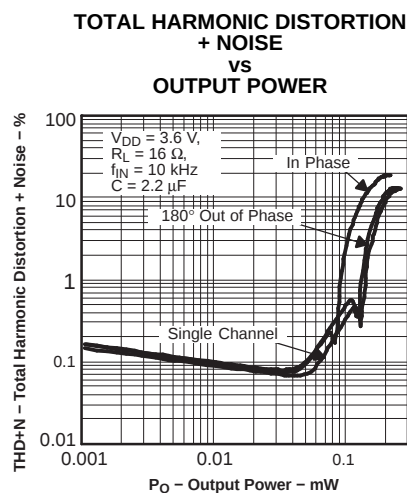


Figure 71.

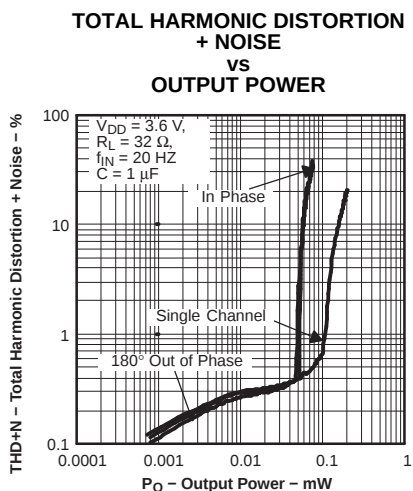


Figure 72.

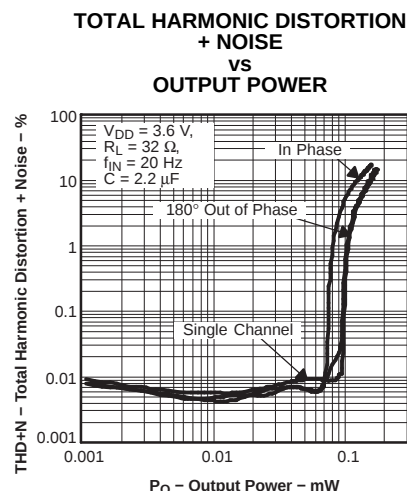


Figure 73.

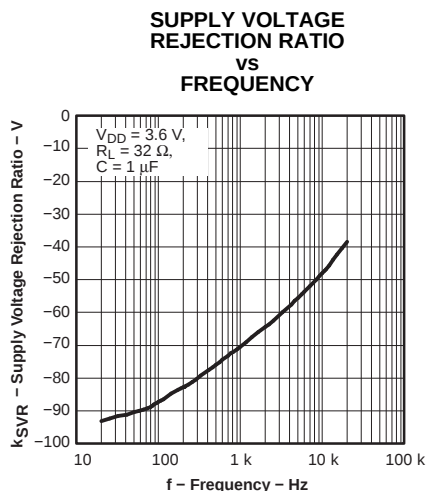


Figure 74.

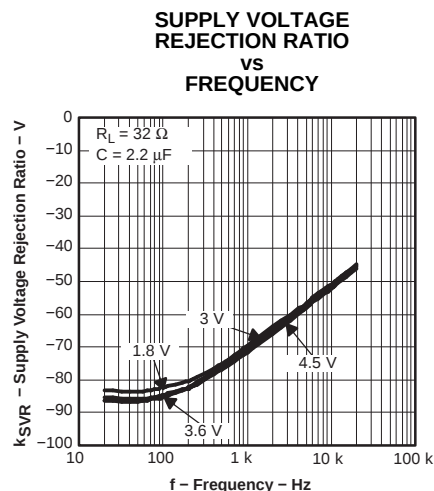


Figure 75.

## Decoupling Capacitors

The TPA4411 and TPA4411M are DirectPath™ headphone amplifiers that require adequate power supply decoupling to ensure that the noise and total harmonic distortion (THD) are low. A good low equivalent-series-resistance (ESR) ceramic capacitor, typically 2.2  $\mu$ F, placed as close as possible to the device  $V_{DD}$  lead works best. Placing this decoupling capacitor close to the TPA4411 or TPA4411M is important for the performance of the amplifier. For filtering lower frequency noise signals, a 10- $\mu$ F or greater capacitor placed near the audio power amplifier would also help, but it is not required in most applications because of the high PSRR of this device.

## Supply Voltage Limiting At 4.5 V

The TPA4411 and TPA4411M have a built-in charge pump which serves to generate a negative rail for the headphone amplifier. Because the headphone amplifier operates from a positive voltage and negative voltage supply, circuitry has been implemented to protect the devices in the amplifier from an overvoltage condition. Once the supply is above 4.5 V, the TPA4411 and TPA4411M can shut down in an overvoltage protection mode to prevent damage to the device. The TPA4411 and TPA4411M resume normal operation once the supply is reduced to 4.5 V or lower.

## Layout Recommendations

### Exposed Pad On TPA4411RTJ and TPA4411MRTJ Package Option

The exposed metal pad on the TPA4411RTJ and TPA4411MRTJ packages must be soldered down to a pad on the PCB in order to maintain reliability. *The pad on the PCB should be allowed to float and not be connected to ground or power.* Connecting this pad to power or ground prevents the device from working properly because it is connected internally to PVSS.

### TPA4411RTJ and TPA4411MRTJ PowerPAD Sizes

Both the TPA4411 and TPA4411M are available in a 4 mm  $\times$  4mm QFN. The exposed pad on the bottom of the package is sized differently between the two devices. The TPA4411RTJ PowerPAD is larger than the TPA4411MRTJ PowerPAD. Please see the layout and mechanical drawings at the end of the datasheet for proper sizing.

## SGND and PGND Connections

The SGND and PGND pins of the TPA4411 and TPA4411M must be routed separately back to the decoupling capacitor in order to provide proper device operation. If the SGND and PGND pins are connected directly to each other, the part functions without risk of failure, but the noise and THD performance do not meet the specifications.

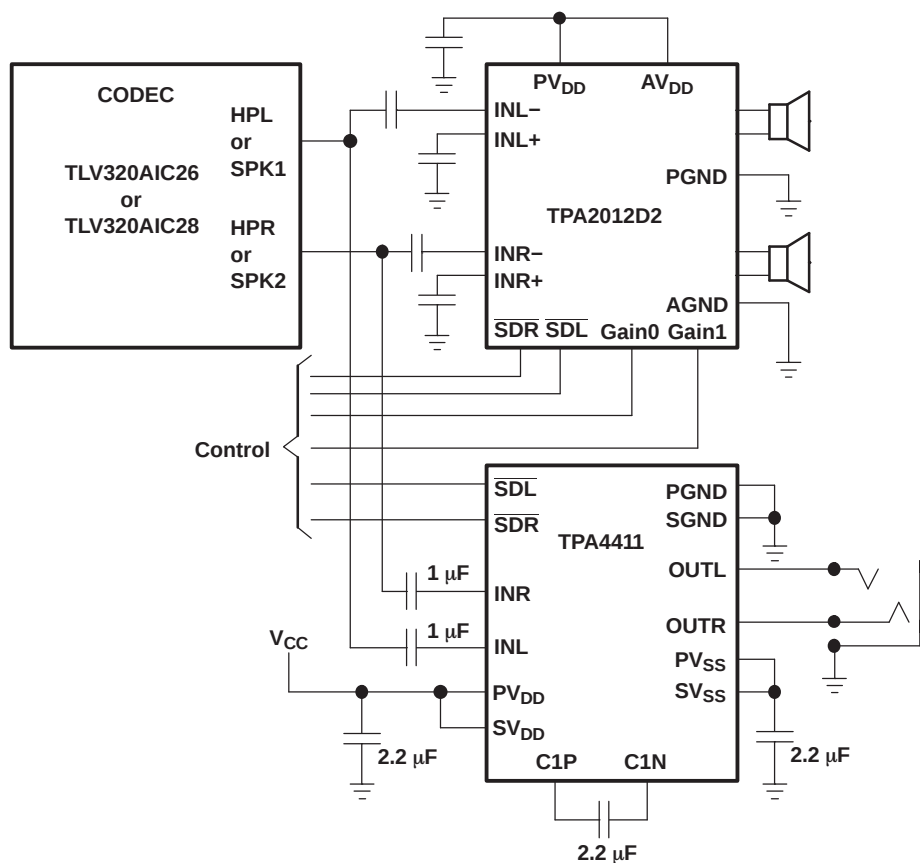
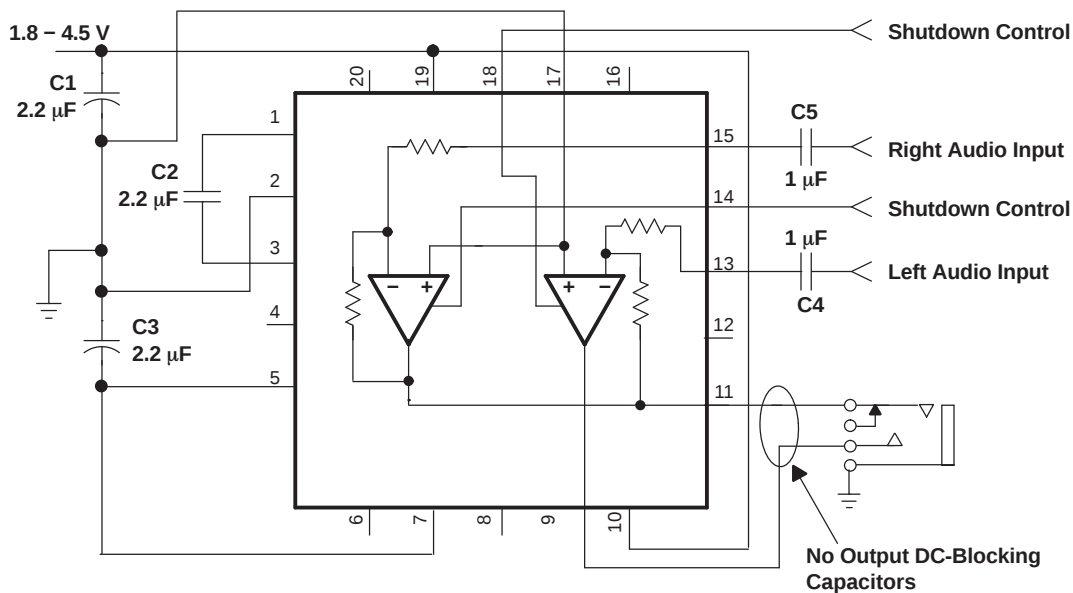


Figure 76. Application Circuit

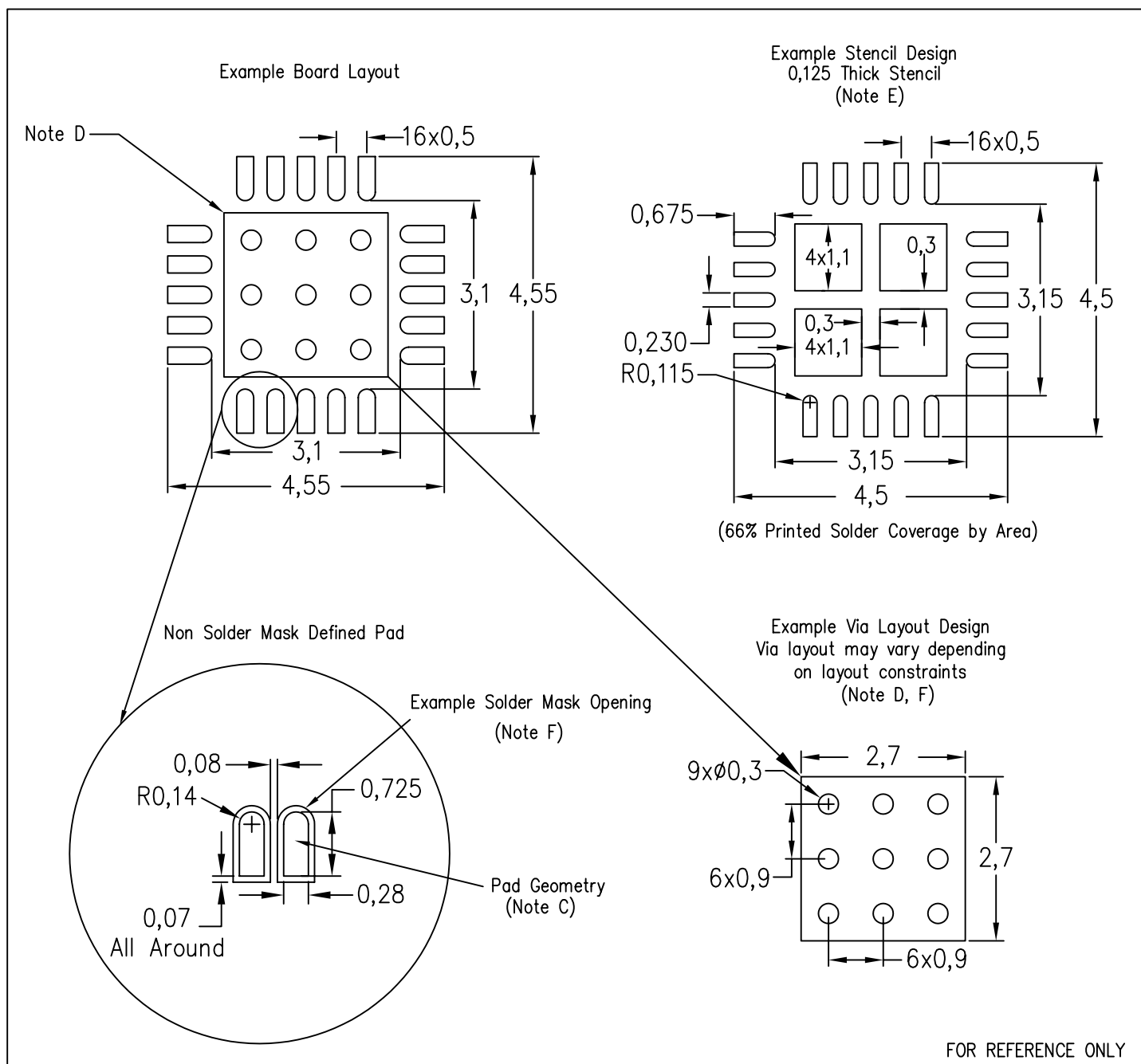


Note: PowerPAD must be soldered down and plane must be floating.

Figure 77. Typical Circuit

TPA4411RTJ

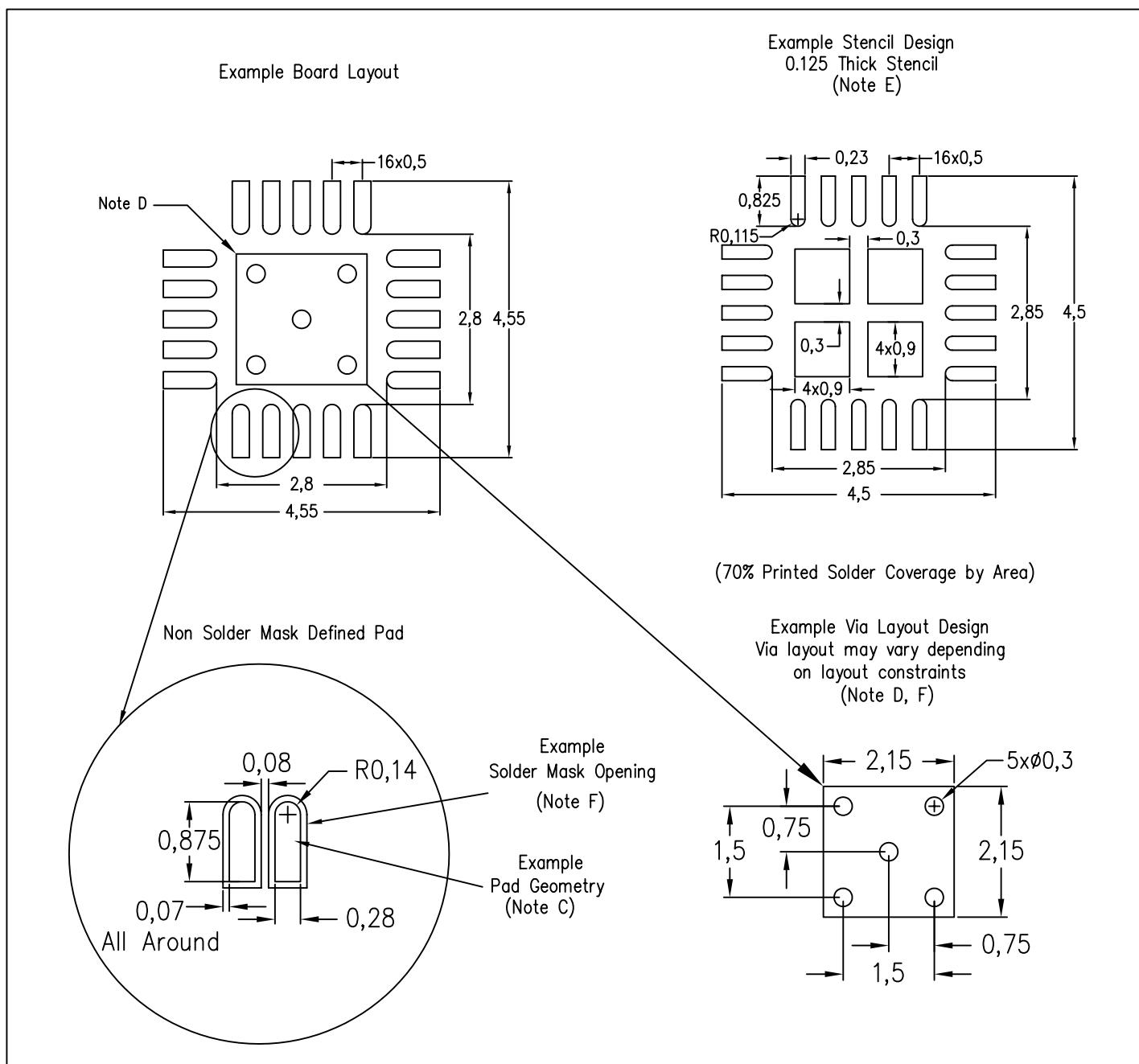
RTJ (S-PQFP-N20)



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-SM-782 is recommended for alternate designs.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.

TPA4411MRTJ

RTJ (S-PQFP-N20)



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-SM-782 is recommended for alternate designs.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.

## PACKAGING INFORMATION

| Orderable part number        | Status<br>(1) | Material type<br>(2) | Package   Pins   | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|------------------------------|---------------|----------------------|------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">TPA4411MRTJR</a> | Active        | Production           | QFN (RTJ)   20   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | BPB                 |
| TPA4411MRTJR.A               | Active        | Production           | QFN (RTJ)   20   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | BPB                 |
| TPA4411MRTJRG4               | Active        | Production           | QFN (RTJ)   20   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | BPB                 |
| TPA4411MRTJRG4.A             | Active        | Production           | QFN (RTJ)   20   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | BPB                 |
| <a href="#">TPA4411MRTJT</a> | Active        | Production           | QFN (RTJ)   20   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | BPB                 |
| TPA4411MRTJT.A               | Active        | Production           | QFN (RTJ)   20   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | BPB                 |
| <a href="#">TPA4411RTJR</a>  | Active        | Production           | QFN (RTJ)   20   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | AKQ                 |
| TPA4411RTJR.A                | Active        | Production           | QFN (RTJ)   20   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | AKQ                 |
| <a href="#">TPA4411RTJT</a>  | Active        | Production           | QFN (RTJ)   20   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | AKQ                 |
| TPA4411RTJT.A                | Active        | Production           | QFN (RTJ)   20   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | AKQ                 |
| <a href="#">TPA4411YZHR</a>  | Active        | Production           | DSBGA (YZH)   16 | 3000   LARGE T&R      | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 85    | AKT                 |
| TPA4411YZHR.A                | Active        | Production           | DSBGA (YZH)   16 | 3000   LARGE T&R      | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 85    | AKT                 |
| <a href="#">TPA4411YZHT</a>  | Active        | Production           | DSBGA (YZH)   16 | 250   SMALL T&R       | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 85    | AKT                 |
| TPA4411YZHT.A                | Active        | Production           | DSBGA (YZH)   16 | 250   SMALL T&R       | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 85    | AKT                 |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPA4411MRTJRG4 | QFN          | RTJ             | 20   | 3000 | 330.0              | 12.4               | 4.25    | 4.25    | 1.15    | 8.0     | 12.0   | Q1            |
| TPA4411YZHR    | DSBGA        | YZH             | 16   | 3000 | 180.0              | 8.4                | 2.38    | 2.4     | 0.8     | 4.0     | 8.0    | Q1            |
| TPA4411YZHT    | DSBGA        | YZH             | 16   | 250  | 180.0              | 8.4                | 2.38    | 2.4     | 0.8     | 4.0     | 8.0    | Q1            |

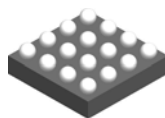
## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPA4411MRTJRG4 | QFN          | RTJ             | 20   | 3000 | 353.0       | 353.0      | 32.0        |
| TPA4411YZHR    | DSBGA        | YZH             | 16   | 3000 | 182.0       | 182.0      | 20.0        |
| TPA4411YZHT    | DSBGA        | YZH             | 16   | 250  | 182.0       | 182.0      | 20.0        |

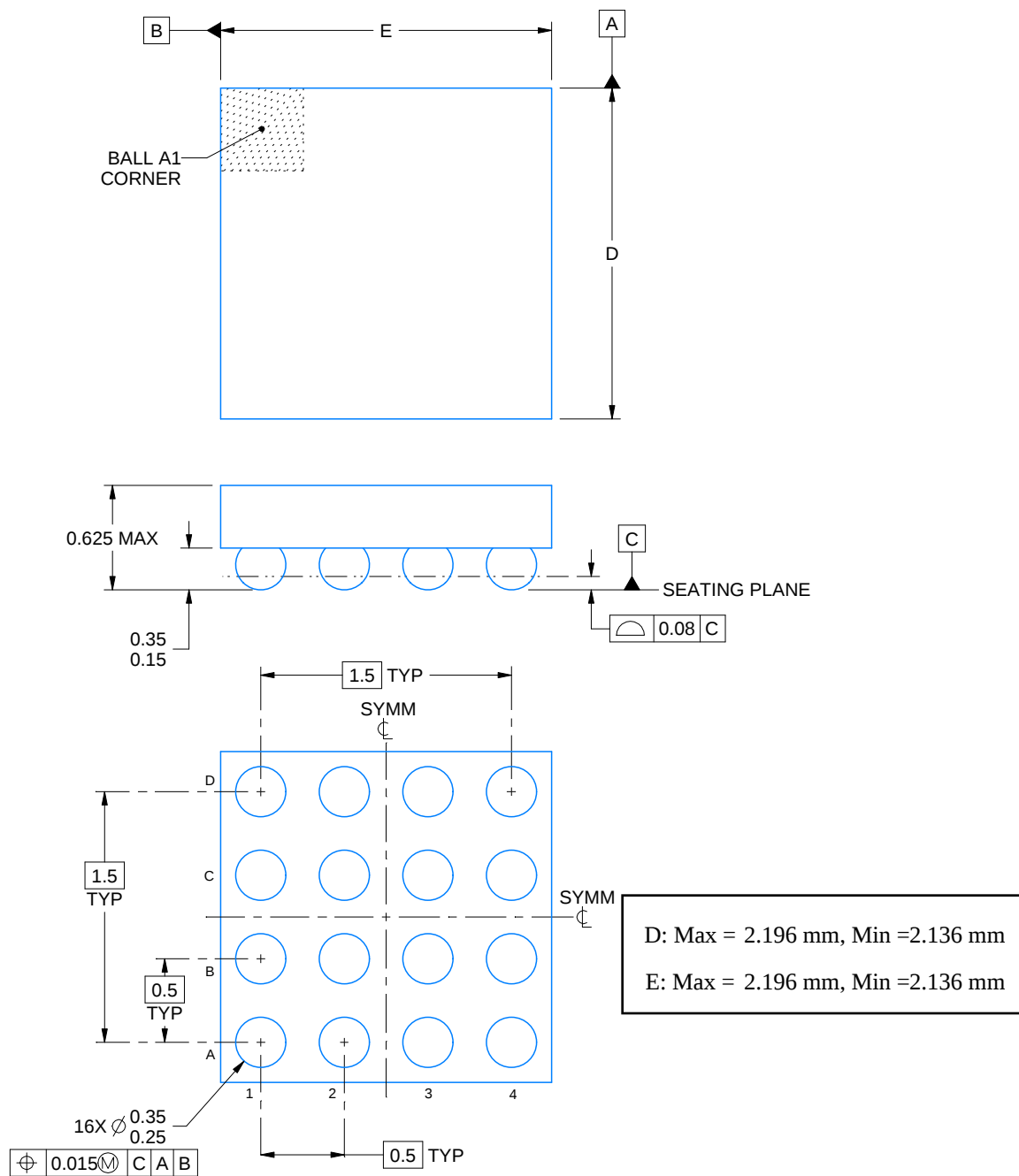
YZH0016



# PACKAGE OUTLINE

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



4226617/A 03/2021

## NOTES:

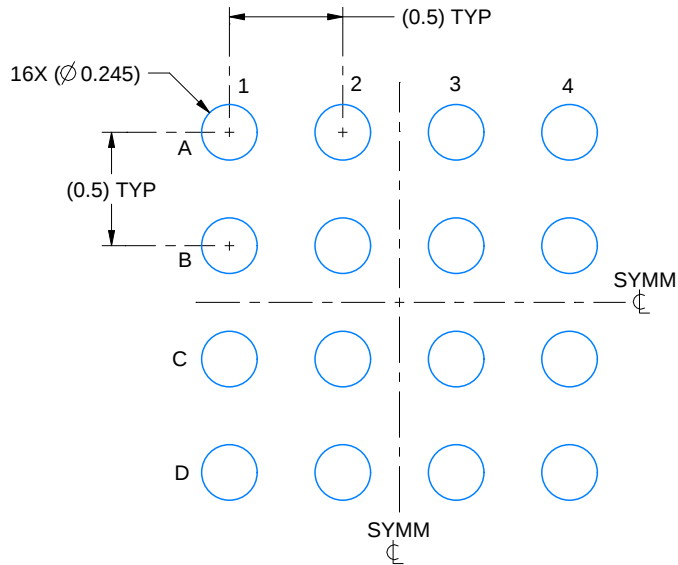
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

# EXAMPLE BOARD LAYOUT

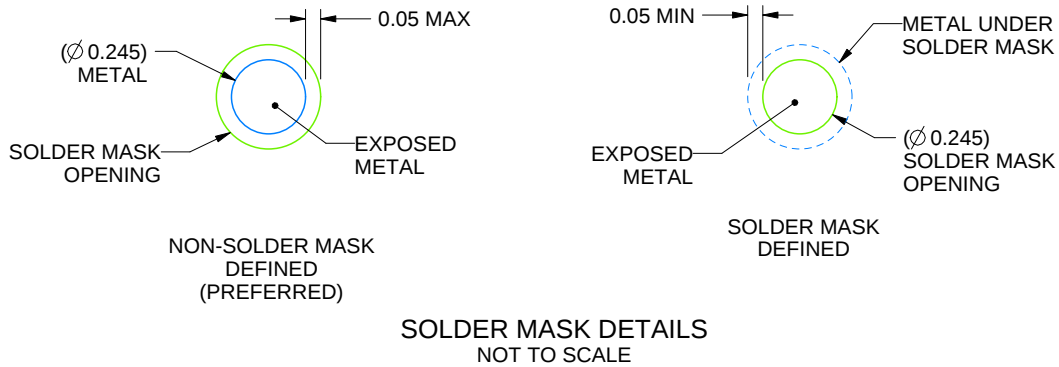
YZH0016

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 30X



SOLDER MASK DETAILS  
NOT TO SCALE

4226617/A 03/2021

NOTES: (continued)

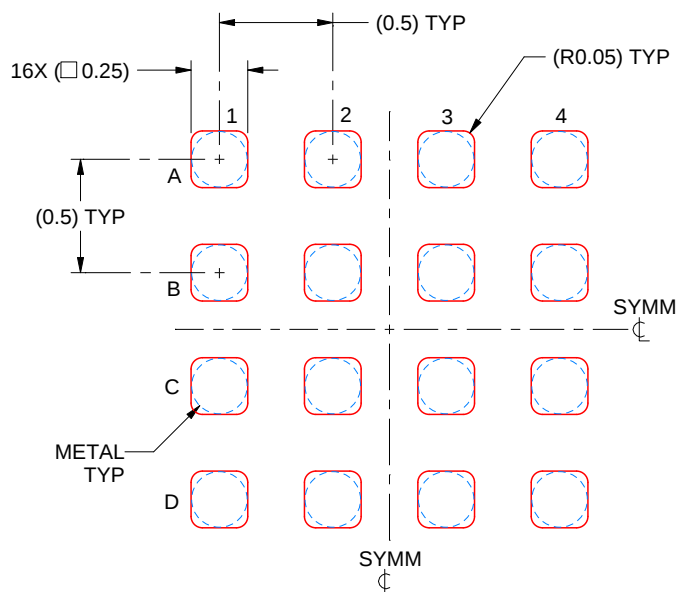
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 ([www.ti.com/lit/snva009](http://www.ti.com/lit/snva009)).

## EXAMPLE STENCIL DESIGN

YZH0016

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE  
BASED ON 0.075 mm THICK STENCIL  
SCALE: 30X

4226617/A 03/2021

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

## GENERIC PACKAGE VIEW

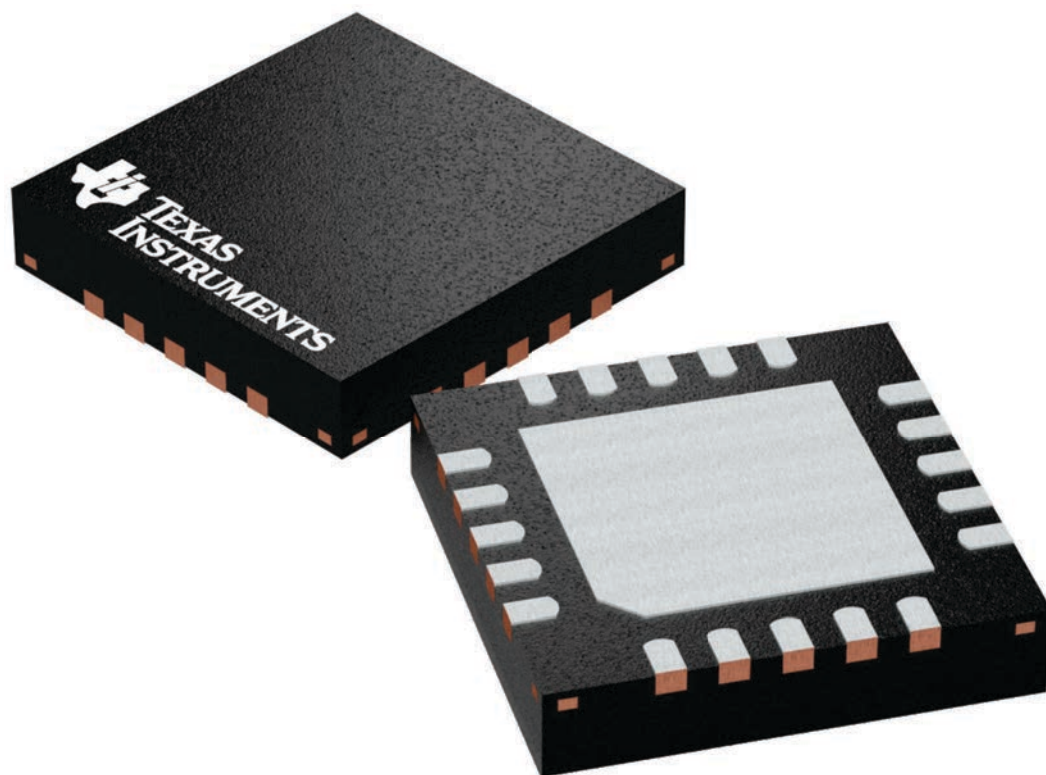
**RTJ 20**

**WQFN - 0.8 mm max height**

4 x 4, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

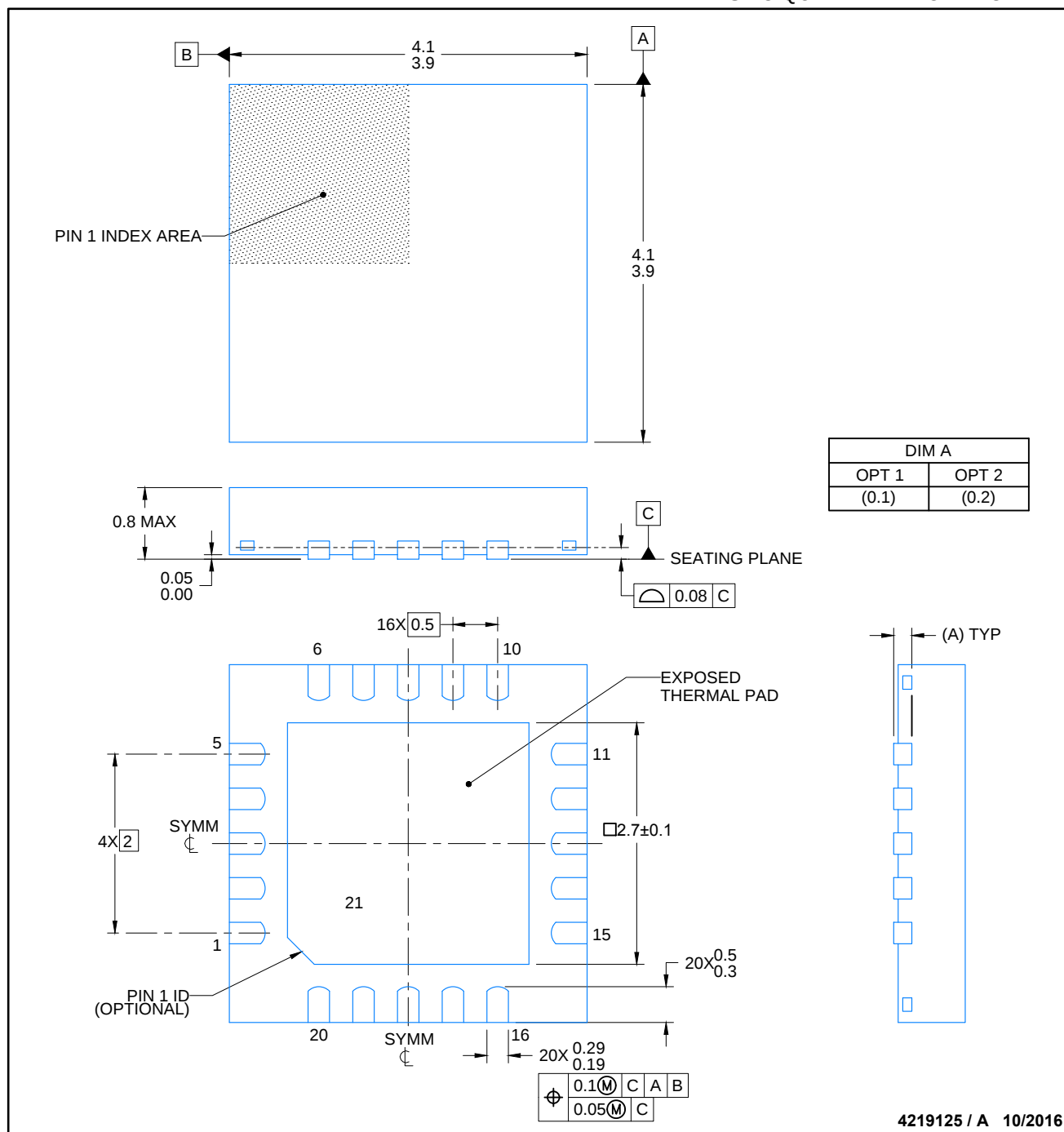
This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



DATA BOOK  
PACKAGE OUTLINE

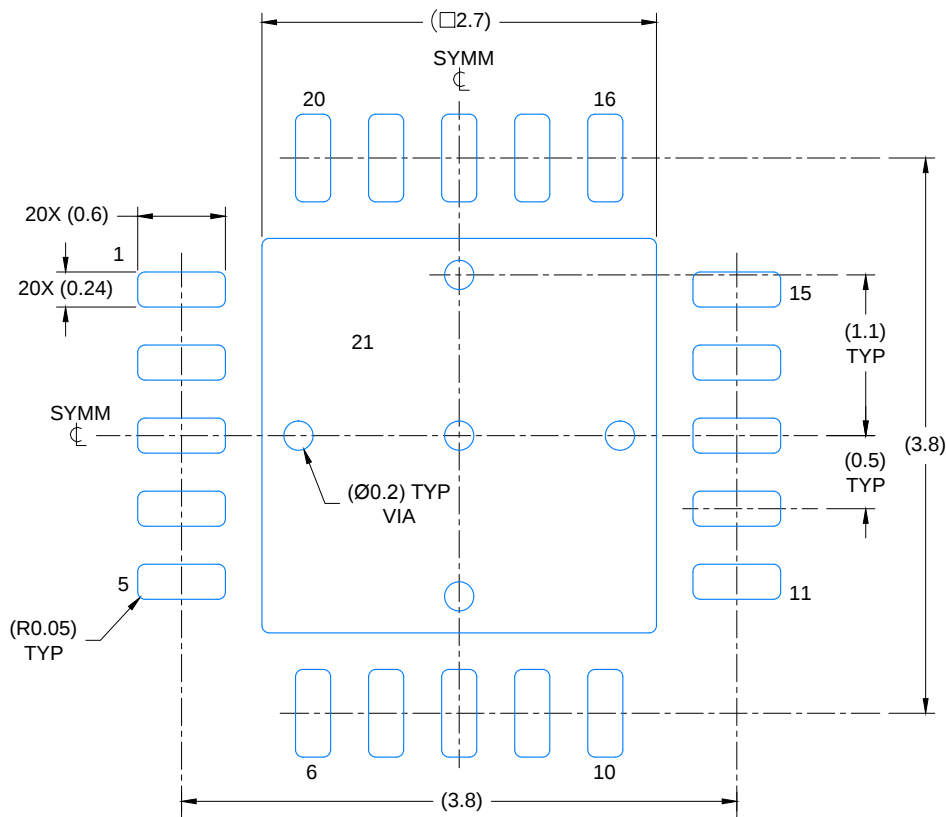
|                   |
|-------------------|
| LEADFRAME EXAMPLE |
| 4222370           |

|                                  |  |                     |                                                                                                                                                                                                                                                               |  |                           |  |
|----------------------------------|--|---------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|---------------------------|--|
| DRAFTSMAN:<br>H. DENG            |  | DATE:<br>09/12/2016 |                                                                                                                                                                                                                                                               |  | DIMENSIONS IN MILLIMETERS |  |
| DESIGNER:<br>H. DENG             |  | DATE:<br>09/12/2016 | <div> <b>TEXAS INSTRUMENTS</b><br/>SEMICONDUCTOR OPERATIONS</div> <div>CODE IDENTITY<br/>NUMBER<br/>01295</div> <div>ePOD, RTJ0020D / WQFN,<br/>20 PIN, 0.5 MM PITCH</div> |  |                           |  |
| CHECKER:<br>V. PAKU & T. LEQUANG |  | DATE:<br>09/12/2016 |                                                                                                                                                                                                                                                               |  |                           |  |
| ENGINEER:<br>T. TANG             |  | DATE:<br>09/12/2016 |                                                                                                                                                                                                                                                               |  |                           |  |
| APPROVED:<br>E. REY & D. CHIN    |  | DATE:<br>10/06/2016 |                                                                                                                                                                                                                                                               |  |                           |  |
| RELEASED:<br>WDM                 |  | DATE:<br>10/24/2016 | <div><div>SCALE<br/>15X</div><div>SIZE<br/>A</div><div>4219125</div><div><div>REV<br/>A</div><div>PAGE<br/>1 OF 5</div></div></div>                                                                                                                           |  |                           |  |
| TEMPLATE INFO:<br>EDGE# 4218519  |  | DATE:<br>04/07/2016 |                                                                                                                                                                                                                                                               |  |                           |  |

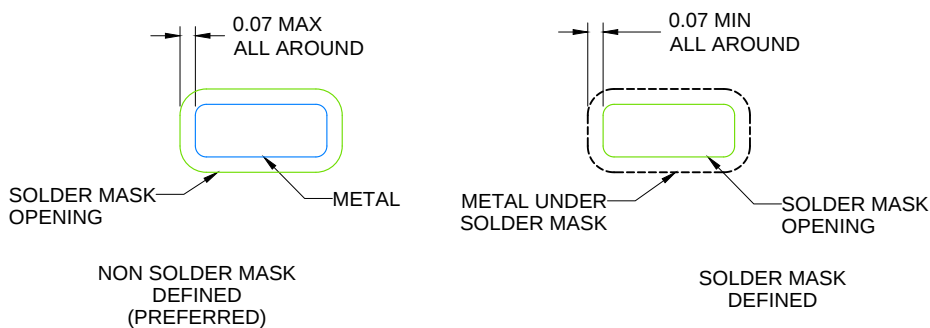


## NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



LAND PATTERN EXAMPLE  
SCALE: 20X

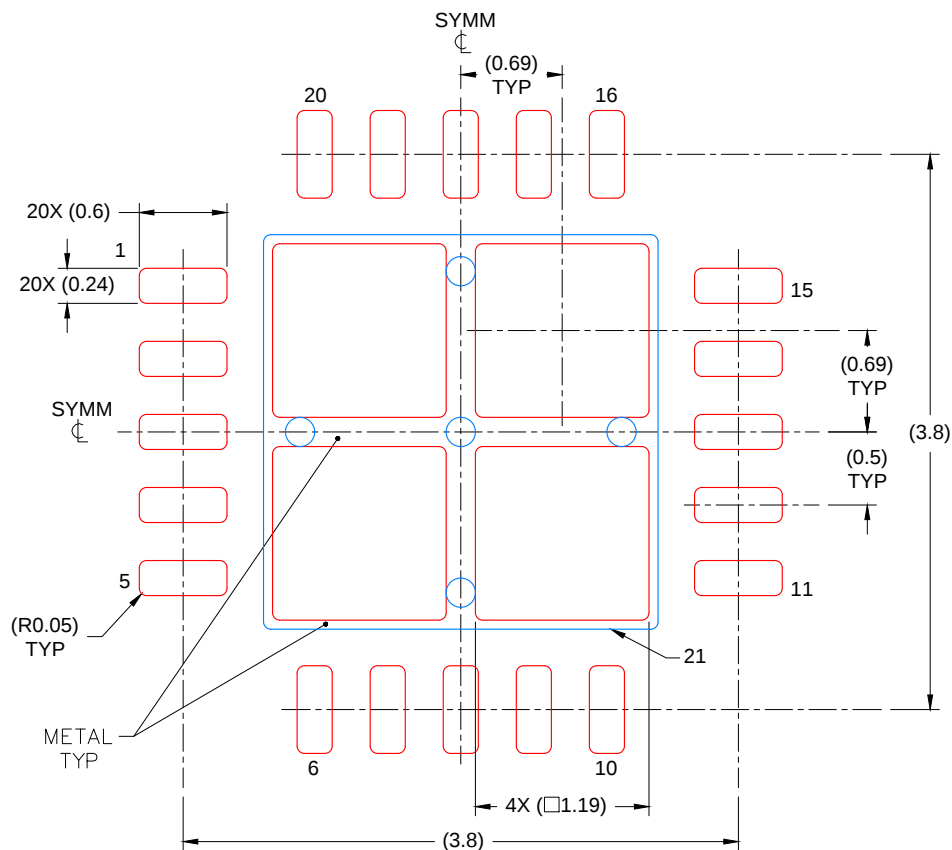


SOLDER MASK DETAILS

4219125 / A 10/2016

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE  
 BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD  
 78% PRINTED COVERAGE BY AREA  
 SCALE: 20X

4219125 / A 10/2016

NOTES: (continued)

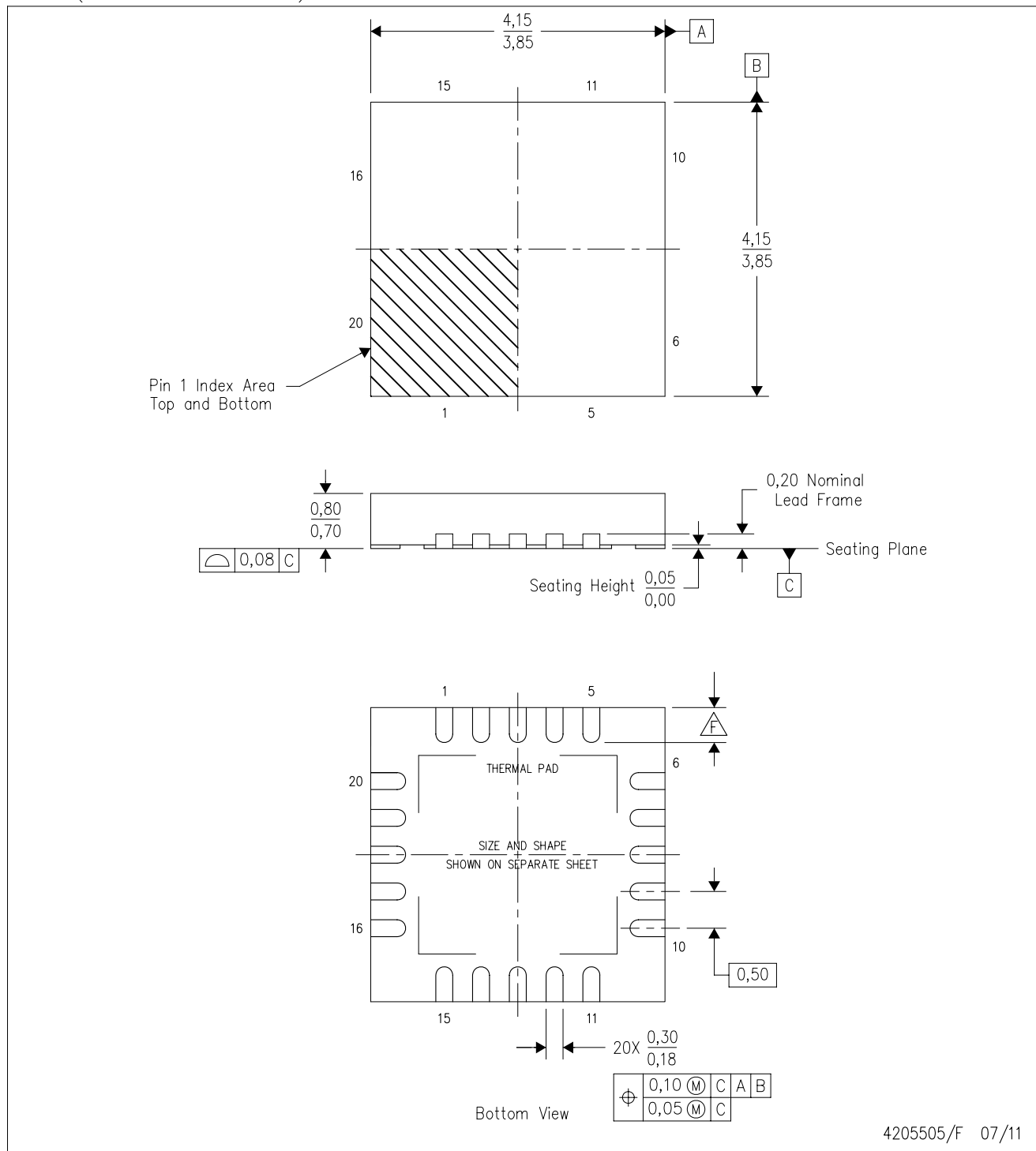
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations..

# REVISIONS

| REV | DESCRIPTION         | ECR     | DATE       | ENGINEER / DRAFTSMAN |
|-----|---------------------|---------|------------|----------------------|
| A   | RELEASE NEW DRAWING | 2160736 | 10/24/2016 | T. TANG / H. DENG    |

RTJ (S-PWQFN-N20)

PLASTIC QUAD FLATPACK NO-LEAD



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994.
  - B. This drawing is subject to change without notice.
  - C. QFN (Quad Flatpack No-Lead) package configuration.
  - D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
  - E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
  - △ Check thermal pad mechanical drawing in the product datasheet for nominal lead length dimensions.

RTJ (S-PWQFN-N20)

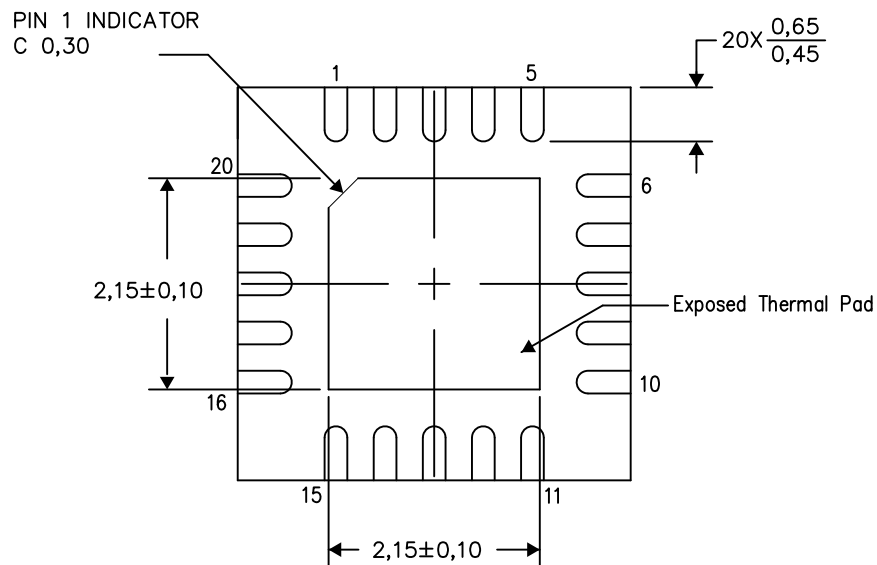
PLASTIC QUAD FLATPACK NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4206256-3/V 05/15

NOTE: All linear dimensions are in millimeters

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Last updated 10/2025